Electromechanical Relays Selection Guide

Latching



JAN









RF





Commercial

Established Reliability

Surface-Mount







Environmental



Attenuated







TELEDYNE RELAYS

A Teledyne Technologies Company





Switching Solutions

Teledyne Relays has been the world's innovative leader in the manufacture of ultraminiature, hermetically sealed, electromechanical and solid-state switching products for more than 40 years. The company's comprehensive product line meets a wide range of requirements for defense and aerospace, industrial, commercial, medical and RF & wireless applications.

Business Focus

- MIL QPL & COTS Solid-State Relays
- MIL QPL & COTS Electromechanical Relays
- HiRel (Space) Electromechanical Relays
- RF & Microwave Relays & Coaxial Switches
- Industrial Solid-State Relays
- Switching Matrices

Markets

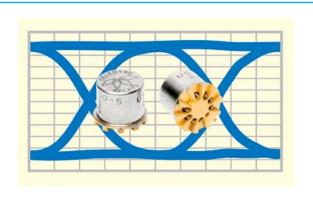
- Commercial & Military Aviation
- Defense & Aerospace
- Telecom/Communications (Wireless)
- Instrumentation & Test
- Industrial Power & Motion Control
- Medical Applications

Product Assurance

Under an aggressive Total Quality Management (TQM) program, Teledyne Relays has embraced a "continuous improvement" culture. With recognized certifications such as AS/EN/JISQ 9100 - Revision B and ISO 9001:9002, DSCC MIL-STD-790 and Boeing D6-82479 Appendix A, Teledyne Relays has become a primary supplier of switching solutions with the highest quality and reliability to industry leaders around the world.

Technical Service & Customer Support

Teledyne Relays provides easy access to technical service and customer support. Our websites make it easy to find technical information, buy products and even get e-mail responses within 24 hours. Switching solutions are only a mouse click away at www.teledynerelays.com or at teledyne-europe.com. Information about coax switches is available at www.teledynecoax.com.



Teledyne Relays offer superior signal integrity up to 12 Gbps. See the RF relays section in our website.

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See specific series for additional features and options

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Teledyne Relays offers a variety of options to customize and meet your specific design needs.



GRF Option TO-5 Relays with straight butt pins for surface-mount applications * RF Relays Only



SGRF Option TO-5 Relays with Gull-Wing (J-Lead) pins for surfacemount applications • RF Relays Only



GRF Option
Centigrid® Relays with
straight butt pins for
surface-mount applications
* RF Relays Only



SGRF Option
TO-5 Relays with Gull-Wing
(J-Lead) pins for surfacemount applications
* RF Relays Only



SRF Option
Relays with Gull-Wing
(J-Lead) pins for surfacemount applications
* RF Relays Only



/S Option
Relays with 0.187"
trimmed leads
See Appendix: Part Numbering



Spacer Pad Option
Relays with polyester film pad
to space between PCB and
Relay Header
See Appendix: Spacer Pad Options



Spreader Pad Option Relays with Diallyl Phthalate pad to spread pins See Appendix: Spreader Pad



/**Q,** /**R** Option
Relays with solder dipped
leads. Pb/Sn (60/40) or
RoHS solder available
See Appendix: Part Numbering System

See specific series for additional features and options

Series RF100/RF103 Electromechanical Relays

The RF100 and RF103 Centigrid® relays are designed to provide improved RF signal repeatability over the frequency range.

The GRF100 and GRF103 Centigrid® relays feature a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

The SGRF100 and SGRF103 Centigrid® relays extend performance advantages over similar RF devices that simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 10Gbps
- · Hermetically Sealed
- High Resistance to ESD
- · Metal Enclosure for EMI shielding
- · High Repeatability
- · Broader bandwidth
- Through-hole or surface-mount configurations

simply offer formed leads for surface
Relay Type
DPDT Non-Latching
Coil Type
100 = Standard Coil
103 = Sensitive Coil
Mounting
RF = Thru-hole GRF = Surface-Mount (Stub) SGRF = Surface-Mount (J-Lead)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C
(a) 7 (b) 1(c) 100 (c)

Part No.		Nominal Coil		Typical RF Performance							
		Voltage	Resistance	Frequency	VSWR	Isola	Insertion Loss				
		(Vdc)	(Ω)	(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)			
(B=2)	RF100	5	50	DC-1	1.1 : 1	35	25	0.2			
RF100	HI 100	12	390	1-2	1.5 : 1	30	20	0.5			
Z-5	RF103	5	100	2-3	1.6 : 1	30	20	0.6			
111	HEIUS	12	800								
	GRF100	5	50	DC-1	1.1 : 1	45	30	0.2			
239		12	390	1-3	1.2 : 1	40	25	0.3			
1000	GRF103	5	100	3-4	1.3 : 1	35	25	0.6			
	GRF103	12	800	4-6	2.2 : 1	30	25	1.2			
	SGRF100	5	50	DC-1	1.2 : 1	35	30	0.2			
(to	Janriou	12	390	1-3	1.3 : 1	30	30	0.7			
1000	SGRF103	5	100	3-4	1.4 : 1	25	25	0.8			
	JGHF103	12	800	4-6	1.8 : 1	25	25	1.0			

Series GRF172 Electromechanical Relays

103

The GRF172 Centigrid® relay is a hermetically sealed, armature relay for 2.5GHz RF applications. Its low profile height .330" (8.38 mm) and .100" (2.54 mm) grid spaced terminals make it an ideal choice where extreme packaging density and/or close PC board spacing are required. The GRF172 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability. The GRF172 extends performance advantages over similar RF devices that simply offer formed leads for surface mounting.

The Series GRF172D has an internal discrete silicon diode for coil suppression.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- · Broader bandwidth
- Through-hole or surface-mount configurations

DPDT Non-Latching
Coil Type
172 = Standard Coil
Diode Option
D = Internal diode for coil
transient suppression
Mounting
GRF = Surface-Mount (Stub)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C

Relay Type

Part No.		Nominal Coil		Typical RF Performance						
		Voltage	Resistance (Ω)	Frequency (GHz)	VSWR (max)	Isola	tion (dB)	Insertion Loss (dB) (max)		
		(Vdc)				Pole to Pole (min)	Across Contacts (min)			
000	GRF172 GRF172D	5	50	DC-1	1.1 : 1	45	30	0.2		
		12	390	1-2	1.2 : 1	40	25	0.3		
		26	100	2-2.5	1.2 : 1	40	25	0.3		





GRF172D

Series RF300/RF303 Electromechanical Relays

The RF300 and RF303 TO-5 relays are designed to provide improved RF signal repeatability over the frequency range.

The GRF300 and GRF303 TO-5 relays feature a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability. The SGRF300 and SGRF303 TO-5 relays extend performance advantages over similar RF devices that simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 10Gbps+
- · Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- Broader bandwidth
- · Through-hole or surface-mount configurations

Relay Type			Nom	Nominal Coil			Typical RF Performance				
DPDT Non-Latching			Voltage	Resistance	Frequency	VSWR	Isolation (dB)		Insertion Loss		
Coil Type			(Vdc)	(Ω)	(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)		
300 = Standard Coil		RF300	5	50	DC-1	1.1 : 1	30	25	0.2		
303 = Sensitive Coil	WE 301	RF300D									
Diode Option	712	HESUUD	12	390	1-2	1.1 : 1	25	20	0.3		
D = Internal diode for coil	396	RF303	5	100	2-3	1.2 : 1	25	20	0.4		
transient suppression		RF303D	12	850							
DD = Internal diode for coil		GRF300	5	50	DC-1	1.1 : 1	40	30	0.2		
transient suppression and	A STREET	GRF300D									
polarity reversal protection		GHESOOD	12	390	1-3	1.1 : 1	40	30	0.2		
Mounting	The state of the s	GRF303	5	100	3-4	1.3 : 1	30	30	0.6		
RF = Thru-hole		GRF303D	12	850	4-6	1.6 : 1	25	25	1.0		
GRF = Surface-Mount (Stub) SGRF = Surface-Mount (J-Lead)		SGRF300	5	50	DC-1	1.2 : 1	40	30	0.2		
SRF = Surface Mount (J-Lead)	37/2	SGRF300D	12	390	1-3	1.2 : 1	40	30	0.4		
Temperature					_						
Storage: -65°C to +125°C	4	SGRF303	5	100	3-4	1.2 : 1	20	25	0.8		
Operating: -55°C to +85°C		SGRF303D	12	850	4-6	1.8 : 1	10	20	1.0		
operating.		SRF300	5	50	DC-1	1.1 : 1	25	25	0.5		
	SRF300D SRF303	12	390	1-3	1.5 : 1	25	25	0.5			
		5	100	3-4	2.0 : 1	15	15	3.0			
		SRF303D	12	850	4-6	2.5 : 1	10	10	4.0		

For RF300DD & RF303DD values please see Datasheet



303



300D 303D



303DD

Series RF312 Electromechanical Relays

The RF312 is designed to improve upon the RF300/RF303 relay's high frequency performance. The RF312 offers monotonic insertion loss over to 8GHz. This improvement in RF insertion loss over the frequency range, makes these relays highly suitable for use in attenuator and other RF circuits.

The GRF312 is designed to improve upon the GRF300/GRF303 relay's high frequency performance. The GRF312 TO-5 relay features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 12Gbps+
- · Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- · Broader bandwidth
- Through-hole or surface-mount configurations

Relay Type
DPDT Non-Latching
Coil Type
312 = Standard Coil
Mounting
RF = Thru-hole
GRF = Surface-Mount (Stub)
SGRF = Surface-Mount (J-Lead)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C



312

		Nominal Coil		Typical RF Performance					
Part N	Part No.		Resistance	Frequency	VSWR	Isola	Insertion Loss		
		(Vdc)	(Ω)	(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)	
(8)		5	50	DC-2	1.2 : 1	30	20	0.2	
9F312-5	RF312	5	50	2-4	1.2 : 1	25	20	0.4	
22847	NF312	12	200	4-6	1.3 : 1	25	20	0.6	
Ш		12	390	6-8	1.4 : 1	20	20	0.8	
200	GRF312	5	50	DC-2	1.4 : 1	40	30	0.3	
				2-4	1.4 : 1	40	30	0.5	
27481 22453		12	390	4-6	1.5 : 1	35	30	1.0	
				6-8	1.5 : 1	35	30	1.5	
		F		DC-2	1.2 : 1	40	30	0.2	
12-5		5	50	2-4	1.2 : 1	35	30	0.5	
19 244	SGRF312		000	4-6	1.3 : 1	30	25	1.0	
		12 390	390	6-8	1.5 : 1	30	25	1.5	

Series RF311/RF331 Electromechanical Relays

The RF311/RF331 relays are designed to provide improved RF signal repeatability over the frequency range. These relays are highly suitable for use in attenuator and other RF circuits.

The GRF311 offers monotonic insertion loss to 8GHz. This improvement in RF insertion loss over the frequency range makes these relays highly suitable for use in attenuator and other RF circuits. The GRF311 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations

mign-nequency performance as well as parametric repeatability.						comigurations				
Relay Type	Part No.		Nomi	nal Coil	Typical RF Performance					
SPDT Non-Latching			Voltage	Resistance	Frequency	VSWR	Isolation Across Contacts (dB)	Ilisertion Loss		
Coil Type			(Vdc)	(Ω)	(GHz)	(max)	(min)	(dB) (max)		
311 = Standard Coil	RF311	5	63	DC-2	1.3 : 1	25	0.2			
331 = Sensitive Coil			12	500	2-4	1.6 : 1	20	0.4		
Mounting RF = Thru-hole		RF311	26	2000	4-6	1.6 : 1	20	0.6		
GRF = Surface-Mount (Stub)					6-8	1.6 : 1	15	0.8		
Temperature	6	GRF311	5	63	DC-2	1.2 : 1	30	0.3		
Storage: -65°C to +125°C Operating: -55°C to +85°C			12	500	2-4	1.5 : 1	25	0.5		
Operating. 33 0 to 100 0	183		26	2000	4-6	1.5 : 1	25	0.7		
					6-8	1.6 : 1	20	1.0		
311 3 • • • 2 331			5	125	DC-2	1.3 : 1	25	0.2		
	4379	RF331	12	1025	2-4	1.6 : 1	20	0.4		
		nr331	26	4000	4-6	1.6 : 1	20	0.6		
					6-8	1.6 : 1	15	0.8		

Series GRF342 Electromechanical Relays

The Series GRF342 relay is a hermetically sealed, RF relay designed from inception for surface mount applications. This magnetic-latching relay features extremely low internal circuit losses for exceptional time and frequency domain response characteristics through and beyond the UHF spectrum and into the S band. The GRF342 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact and pole-to-pole isolation. This ground shield provides an RF ground interface that results in improved high-frequency performance as well as parametric repeatability. The GRF342 extends performance advantages over similar RF devices that simply offer formed leads for surface mounting.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- · Broader bandwidth
- Through-hole or surface-mount configurations

erformance tion (dB)

Across Contacts

35

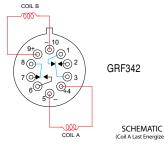
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Relay Type		Nom	inal Coil	Typical RF Per			
DPDT Magnetic-Latching	Part No.	Voltage	Resistance	Frequency	VSWR (max)	Isolati	
Coil Type		(Vdc)	(Ω)	(GHz)		Pole to Pole (min)	
342 = Standard Coil	distributed to	5	50	DC-2	1.1 : 1	40	
Mounting	A Part	3	30	DO-2		40	
GRF = Surface-Mount (Stub)	GRF342	12	390	2-4	1.2 : 1	30	
Temperature				4-6	1.4 : 1	25	
Storage: -65°C to +125°C							

Schematics as viewed from terminals

Operating: -55°C to +85°C



Insertion Loss

(dB) (max)

0.3

0.4

8.0

Series RF180 Electromechanical Relays

The Series RF180 relay is a hermetically sealed, magnetic-latching relay featuring extremely low intercontact capacitance for exceptional RF performance over the full UHF spectrum. Its low profile height and .100" (2.54 mm) grid spaced terminals make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The GRF180 features a unique ground shield that isolates and shields each lead to ensure excellent contactto-contact and pole-to-pole isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 10Gbps
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding · High Repeatability
- · Broader bandwidth
- · Through-hole or surface-mount configurations

Relay Type	
DPDT Magnetic-Latching	
Coil Type	
180 = Standard Coil	_
Mounting	
RF = Thru-hole GRF = Surface-Mount (Stub)	7
Temperature	
Storage: -65°C to +125°C	
Operating: -55°C to +85°C	Caret
COIL B	
9 0 0 1 8 0 2 7 0 3 8 0 4	
	CHEMATIC B Last Energized

Nominal Coil			inal Coil	Typical RF Performance						
Part No.		Voltage	Resistance	Frequency	VSWR	Isola	tion (dB)	Insertion Loss		
		(Vdc)	(Ω)	(GHz)	(max)	Pole to Pole (min)	Across Contacts (min)	(dB) (max)		
The state of the s		5	61	DC-2	1.3 : 1	50	30	0.2		
RF	180	12	500	2-4	1.3 : 1	45	30	0.3		
		26	2000	4-6	2.0 : 1	30	25	1.5		
		5	61	DC-2	1.2 : 1	50	35	0.2		
GRI	F180	12	500	2-4	1.3 : 1	35	30	0.4		
00.00		26	2000	4-6	2.0 : 1	25	30	1.5		

Series RF341 Electromechanical Relays

The RF341 series relay is an ultraminiature, hermetically sealed, magnetic-latching relay featuring extremely low intercontact capacitance for exceptional RF performance well into the C band. Its low profile and small size make it ideal for applications where extreme packaging density and/or close PC board spacing are required. Due to its minimal mass, many relays may be used to configure replacements for bulkier switching solutions at substantial savings in weight. The RF341 design has been optimized by increasing the distance between the set/reset contacts. This design improvement makes these unique relays the perfect choice for use in RF attenuators, RF switching matrices and other RF applications requiring high isolation, low insertion loss and low VSWR.

The GRF341 features a unique ground shield that isolates and shields each lead to ensure excellent contactto-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- Excellent Signal integrity up to 10Gbps
- · Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- · Broader bandwidth
- · Through-hole or surface-mount configurations

Relay Type
SPDT Magnetic-Latching
Coil Type
341 = Standard Coil
Mounting
RF = Thru-hole
GRF = Surface-Mount (Stub)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C
+ COIL B

	Nomi	nal Coil		Typica	I RF Performance	
Part No.	Voltage (Vdc)	Resistance (Ω)	Frequency (GHz)	VSWR (max)	Isolation Across Contacts (dB) (min)	Insertion Loss (dB) (max)
Constant S	5	61	DC-2	1.2 : 1	30	0.5
08111 38 477 RF341	12	500	2-4	1.2 : 1	25	0.8
HF341	26	2000	4-6	1.4 : 1	20	2.0
formace & The Control of the Control	5	61	DC-2	1.2 : 1	35	0.3
GRF341	12	500	2-4	1.3 : 1	30	0.7
GRF341	26	2000	4-6	1.4 : 1	25	1.5

SCHEMATIC

Series RF310/RF313 Electromechanical Relays

The ultraminiature RF310 and RF313 relays are designed with an internal bypass (through path), when the coil is de-energized, to provide low insertion loss and VSWR through the bypass and simplicity of design for the user. Relays have improved RF insertion loss repeatability over the frequency range from DC to 3 GHz. Highly suitable for use in attenuator, linear amplifier and other RF circuits.

- · N.C. bypass configuration
- · Repeatable insertion loss
- · Broad Bandwidth

- · Metal Enclosure for EMI shielding
- · Ground pin option to improve ground case RF grounding
- · High isolation between control and signal path

Relay Type
Normally Closed Bypass
Coil Type
310 = Standard Coil
313 = Sensitive Coil
Mounting
RF = Thru-hole
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C
_

Nominal Coil				Typical RF Performance							
Part N	Part No.		Resistance	Frequency	VSWR		Isolation (dB)		Insertion Loss (dB)		
		(Vdc)	(Ω)	(GHz)	N.O. (max)	Bypass (max)	N.O. (min)	Bypass (min)	N.O. (max)	Bypass (max)	
OF THE		5	50	DC-1	1.2 : 1	1.3 : 1	35	25	0.2	0.3	
-	RF310	12	390	1-2	1.2 : 1	1.3 : 1	25	25	0.3	0.4	
///				2-3	1.4 : 1	1.3 : 1	25	20	0.4	0.5	
-		5	100	DC-1	1.2 : 1	1.3 : 1	35	25	0.2	0.3	
-	RF313	12	850	1-2	1.2 : 1	1.3 : 1	25	25	0.3	0.4	
/11				2-3	1.5 : 1	1.3 : 1	25	20	0.5	0.4	



RF310 RF313

Series RF320/RF323 Electromechanical Relays

The ultraminiature RF320 and RF323 relays are designed with an internal bypass (through path), when the coil is energized, to provide low insertion loss and VSWR through the bypass and simplicity of design for the user. The RF320 and RF323 relays have improved RF insertion loss repeatability over the frequency range from DC to 3 GHz. Highly suitable for use in attenuator, linear amplifier and other RF circuits.

- · N.O. bypass configuration
- · Repeatable insertion loss
- · Broad Bandwidth

- Metal Enclosure for EMI shielding
- · Ground pin option to improve ground case RF grounding
- High isolation between control and signal path

Helay Type
Normally Open Bypass
Coil Type
320 = Standard Coil
323 = Sensitive Coil
Mounting
RF = Thru-hole
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C



RF320 RF323

Nominal Coil				Typical RF Performance						
Part No.		Voltage	Resistance	Frequency	VSWR		Isolation (dB)		Insertion Loss (dB)	
		(Vdc)	(Ω)	(GHz)	N.C. (max)	Bypass (max)	N.C. (min)	Bypass (min)	N.C. (max)	Bypass (max)
RF320		5	50	DC-1	1.2 : 1	1.4 : 1	30	25	0.2	0.4
-12	RF320	12	390	1-2	1.2 : 1	1.4 : 1	30	20	0.3	0.4
11111				2-3	1.4 : 1	1.4 : 1	25	20	0.4	0.6
AF323		5	100	DC-1	1.2 : 1	1.4 : 1	30	25	0.2	0.4
- 100000	RF323	12	850	1-2	1.2 : 1	1.4 : 1	30	20	0.3	0.4
#111				2-3	1.4 : 1	1.4 : 1	25	20	0.4	0.5

Series A150 Electromechanical Relays

The Series A150 ultraminiature Attenuator Relays are designed for attenuating RF signals in 50-ohm systems over a frequency range from DC to 3 GHz. Their low profile and small grid spacing makes them ideal for use when packaging density is a prime consideration. The A150 relays eliminate the need for additional external resistors.

These single section, switchable attenuator relays have internal matched thin film attenuator pads in "L," "T" or "Pi" configurations, as applicable. Relays are available in fixed increments of 1, 2, 3, 4, 5, 6, 8, 10, 16 and 20 dB, which can be used singly or in combination to achieve the attenuation levels desired.

The GA150 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- · Excellent phase linearity
- Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- · High Repeatability
- · Broader bandwidth
- · Through-hole or surface-mount configurations

Relay Type
RF Attenuator
Coil Type
A150 = Standard Coil
Mounting
A = Thru-hole GA = Surface-Mount (Stub)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C
3 5 ● ──────●

Clorage. 00	0 10 1 12	
Operating: -5	5°C to ⊦	-85
3 5 6 1 7 7 SCHEMATIC (Bottom View)	150	J

		Nomir	nal Coil		Туріса	I RF Perfor	mance		
Part No.		Voltage	Resistance		vsi	WR	Insertion Loss (dB)		
		(Vdc)	(Ω)	(GHz)	Attenuated Path (Typ.)	Thru Path (Max.)	Тур.	Max.	
		5	50	DC-1	1.20 : 1	1.10 : 1	0.1	0.25	
	A150	12	390	1-2	1.30 : 1	1.20 : 1	0.2	0.35	
TIT	AISU	15	610	2-3	1.40 : 1	1.25 : 1	0.3	0.55	
1111111		26	1560						
		5	50	DC-1	1.20 : 1	1.20 : 1	0.1	0.25	
GA150-10-12	GA150	12	390	1-2	1.20 : 1	1.20 : 1	0.2	0.35	
030305030	GAISU	15	610	2-3	1.20 : 1	1.30 : 1	0.3	0.45	
		26	1560						

Series A152 Electromechanical Relays

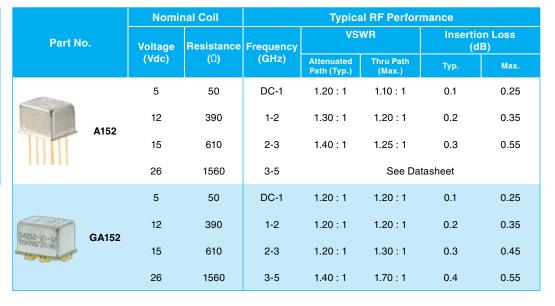
The Series A152 highly repeatable ultraminiature attenuator relays are designed for attenuating RF signals in 50-ohm systems over a frequency range from DC to 5 GHz. Their low profile and small grid spacing makes them ideal for use when packaging density is a prime consideration. The A152 relays eliminate the need for additional external resistors/attenuators.

These single section, switchable attenuator relays have an internal matched thin film attenuator pad in a "Pi" configuration. Relays are available in a fixed increment of 20 dB. (Other values available) The GA152 features a unique ground shield that isolates and shields each lead to ensure excellent contact-to-contact isolation. This ground shield provides a ground interface that results in improved high-frequency performance as well as parametric repeatability.

- · Hermetically Sealed
- · High Resistance to ESD
- Metal Enclosure for EMI shielding
- High Repeatability
- Broader bandwidth
- Through-hole or surface-mount configurations

Relay Type
RF Attenuator
Coil Type
A152 = Standard Coil
Mounting
A = Thru-hole
GA = Surface-Mount (Stub)
Temperature
Storage: -65°C to +125°C
Operating: -55°C to +85°C
3 ● ─ ─ ─ ─ ●

152



SCHEMATIC

COMMERCIAL RELAYS

Series 122C Electromechanical Relays

The 122C Centigrid® magnetic-latching relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The basic operating function and internal structure are similar to Teledyne's TO-5, 422 relay series. The 122C is capable of meeting Teledyne Relays' T2R® requirements.

The Series 122C relay has internal silicon diodes for coil suppression, Zener diodes to protect the MOSFET gate inputs, and N-channel enhancement-mode MOSFET chips, which enable direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

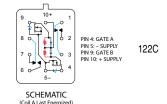
The 122C magnetic-latching relay is ideally suited for applications where coil operating power must be minimized. The relays can be operated with a short-duration pulse. After the contacts have transferred, no external coil power is required.

The magnetic-latching feature of the Series 122C relay provides a "memory" capability, since the relays will not reset upon removal of coil power.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
 High force mass ratio for resistance to shock
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Relay Type					
DPDT Magnet	DPDT Magnetic-Latching					
CMOS	Feature					
Internal power	MOSFET					
driver and dioc	de coil					
suppression						
Vibration	Vibration Shock					
30 g's	100 g's 6 msec,					
to 3000 Hz	half-sine					
Accele	eration					
50	50 g's					
Temperature						
Storage: -65°	C to +125°C					
Operating: -5	5°C to +85°C					

			Nom	inal Coil			
Part No.		Voltage Coil Cu			Operating	Latch and	Contact Load Rating
		(Vdc)	Min.	Max.	Power (mW)	Reset Voltage (Vdc) (Max)	
		5	82.2	114.9	505	3.5	Resistive: 1A/28Vdc
Piliting		6	41.6	57.0	296	4.5	Inductive: 200mA/28Vdc (320mH)
	122C	9	27.4	37.2	288	6.8	Lamp: 100mA/28Vdc
	1220	12	20.5	27.8	287	9.0	Low Level: 10 to 50 uA/10 to 50 mV
		18	13.7	18.2	286	13.5	
1 1111111		26	11.4	15.2	351	18.0	



Series 172 Electromechanical Relays

The 172 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay for commercial applications. Its low profile height .280" (7.11 mm) and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it an ideal choice where extreme packaging density and/or close PC board spacing are required.

The Series 172 relay has an internal discrete silicon diode for coil transient suppression.

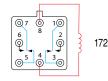
By virtue of its inherently low intercontact capacitance and contact circuit losses, the 172 relay is an excellent subminiature RF switch for frequencies well into the UHF spectrum. Applications include telecommunications, test instruments, mobile communications, attenuators, and automatic test equipment.

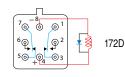
- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type						
DPDT Non-Latching						
Diode Options						
D = Internal diode for coil						
transient suppression						
Vibration Shock						
10 g's to 500 Hz	30 g's 6 msec,					
half-sine						
Temperature						
Storage: -65°C to +125°C						
Operating: -5	5°C to +85°C					

Schematics as viewed from termin	nals

			Nomi	nal Coil		
Part No).	Voltage (Vdc)	Resistance (Ω)	P.U.V (Vdc) (max.)	Operating Power (mW)	Contact Load Rating
		3	39	2.25	235	Resistive: 1A/28Vdc
176-5	172	5	64	3.8	405	Inductive: 200mA/28Vdc (320mH)
456 35	172D	12	400	9.0	360	Lamp: 100mA/28Vdc
		26	1600	18.0	440	Low Level: 10 to 50 uA/10 to 50 mV





P.U.V = Pick-Up Voltage

COMMERCIAL RELAYS

Series 712 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the Series 712 relays are some of the most versatile ultraminiature relays available because of their small size and low coil power dissipation.

The Series 712D relay has an internal discrete silicon diode for coil transient suppression. The hybrid Series 712TN relay has an internal silicon diode and transistor driver. The integrated packaging of the relay with its associated semiconductor devices greatly reduces PC board floor space requirements as well as component installation costs.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 712 has proven to be excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

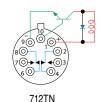
- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type						
DPDT Non-Latching						
Diode (Options					
D = Internal did	ode for coil					
transient supp	ression					
TN = Internal t	ransistor driver					
and coil transient suppression						
diode						
Vibration	Shock					
10 a'o to 500 Hz	30 g's 6 msec,					
10 g's to 500 Hz	half-sine					
Tempe	erature					
Storage: -65°C to +125°C						
Operating: -5	5°C to +85°C					
Operating: -5	5 C 10 +85°C					

			Nom	inal Coil		
Part N	Part No.		(Vdc) (O) (Vdc) (max.) to Turn		Base Current to Turn On (712 TN only)	Contact Load Rating
1		5	50	3.6	3.00	Resistive: 1A/28Vdc
738	712	6	98	4.2	2.04	Inductive: 200mA/28Vdc (320mH)
-12	712D	9	220	6.5	1.36	Lamp: 100mA/28Vdc
1111	712D 712TN	12	390	8.4	1.03	Low Level: 10 to 50 uA/10 to 50 mV
1111	/ 12 I IN	18	880	13.0	0.68	
1111		26	1560	17.0	0.50	







Schematics as viewed from terminals

Series 722 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the 722 relay has become one of the most versatile ultraminiature relays available because of its small size and low coil power dissipation.

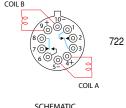
The Series 722D relay has discrete silicon diodes for coil transient suppression.

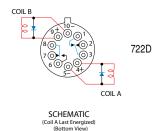
The Series 722 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse and after the contacts have transferred, no external coil power is required. The magnetic-latching feature of the Series 722 provides a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type					
DPDT Magnetic-Latching					
Diode (Options				
D = Internal diode for coil					
transient suppression					
Vibration	Shock				
10 g's to 500 Hz	30 g's 6 msec, half-sine				
Temperature					
Storage: -65° Operating: -5					

			Nominal C	oil				
Part No.		Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating			
1		5	61	3.5	Resistive: 1A/28Vdc			
722-1		6	120	4.5	Inductive: 200mA/28Vdc (320mH)			
38290	722	9	280	6.8	Lamp: 100mA/28Vdc			
ITAL	722D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV			
4104		18	1130	13.5				
WIII.		26	2000	18.0				





COMMERCIAL RELAYS

Series 732 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, the Series 732 relay is one of the most versatile ultraminiature relays available because of their small size and low coil power dissipation. The sensitive 732 relay has a high resistance coil, thus requiring extremely low operating power (200 mW typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series 732D relay has an internal discrete silicon diode for coil transient suppression. The hybrid Series 732TN relay has an internal silicon diode and transistor driver. The integrated packaging of the relay with its associated semiconductor devices greatly reduces PC board floor space requirements as well as component installation costs.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 732 has proven to be excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
 High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Polov	Type				Nom	inal Coil		
Relay					NOIII	mai Coli		
DPD1 Non-Lat	DPDT Non-Latching Coil Diode Options		Part No.		Resistance (Ω)	P.U.V (Vdc) (max.)	Base Current to Turn On (712 TN only)	Contact Load Rating
Diode (
D = Internal did	ode for coil						(712 TN Only)	
transient suppression TN = Internal transistor driver and coil transient suppression diode		080	732 732D 732TN	5	100	3.5	1.50	Resistive: 1A/28Vdc
		M. Hirtmann		6	200	4.5	1.00	Inductive: 200mA/28Vdc (320mH)
				9	400	6.8	0.75	Lamp: 100mA/28Vdc
				12	850	9.0	0.47	Low Level: 10 to 50 uA/10 to 50 mV
Vibration	Shock		/321N	18	1600	13.5	0.38	
	30 q's 6 msec,	// N A 1 \		26	3300	18.0	0.24	
10 g's to 500 Hz 30 g's 6 msec, half-sine								
Temperature								







Schematics as viewed from terminals

Storage: -65° C to $+125^{\circ}$ C Operating: -55° C to $+85^{\circ}$ C

COMMERCIAL SURFACE-MOUNT RELAYS

Series S114 & S134 Electromechanical Relays

The Series S114 Surface Mount Centigrid® Relay is an ultraminiature, hermetically sealed, armature relay. The low profile height .360" (9.14 mm) and .100" (2.54 mm) lead spacing make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The specially formed leads are pre-tinned to make the relays ideal for most types of surface mount solder reflow processes.

The basic design and internal construction are identical to the Series 114 & 134 Centigrid® relays, and are capable of meeting Teledyne Relays' T2R® requirements.

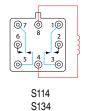
The S114D and S114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

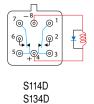
The sensitive S134 surface mount Centigrid® Relay has a high resistance coil, thus requiring extremely low operating power (200 mW typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity

- · High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре				Non	ninal Coil			
DPDT Non-Latching Coil Type		Part N	o.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
S114 = Standa	rd Coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
S134 = Sensiti	ve Coil	124		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode (Options	13	S114	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal die	ode for coil	12 - TO	S114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
transient supp	ression	174		18	880	13.5	0.59	10.0	
DD = Internal o	liode for coil			26	1560	18.0	0.89	13.0	
transient supp	ression and			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
polarity revers	al protection			6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Vibration	Shock		S114DD	9	220	7.8	8.0	5.3	Lamp: 100mA/28Vdc
30 g's to 3000	75 g's 6 msec,			12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
30 g s to 3000 Hz	half-sine			18	880	14.5	1.1	10.0	
Accele				26	1560	19.0	1.4	13.0	
				5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc
50	50 g's			6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Tempe	erature	图图	S134	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
Storage: -65°	C to +125°C	An Elle	S134D	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
Operating: -5	5°C to +85°C	199		18	1600	13.5	0.59	10.0	
				26	3200	18.0	0.89	13.0	
				5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
				6	125	4.8	8.0	3.0	Inductive: 200mA/28Vdc (320mH)
			S134DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
		An F	010400	12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
		140		18	1600	14.5	1.1	9.0	
		-		26	3200	19.0	1.3	13.0	







S114DD S134DD

COMMERCIAL SURFACE-MOUNT RELAYS

Series S172 Electromechanical Relays

The S172 surface mount Centigrid® relay is an ultraminiature, hermetically sealed, armature relay for commercial applications. Its low profile height .470" (11.94 mm) and .100" (2.54 mm) grid spaced terminals make it an ideal choice where extreme packaging density and/or close PC board spacing are required. The specially formed surface-mount leads are pre-tinned to make the relays ideal for all types of surface-mount solder reflow processes.

The basic design and internal structure are similar to Teledyne's DPDT 114 Centigrid® relay. (see page 16) The S172D relay has an internal discrete silicon diode for coil transient suppression.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type					
DPDT Non-Lat	ching				
Diode (Options				
D = Internal did	ode for coil				
transient suppression					
Vibration	Shock				
10 g's to 500 Hz	30 g's 6 msec, half-sine				
Tempe	erature				
Storage: -65° Operating: -5					

			Nomin	al Coil			
Part No.		Voltage (Vdc)			Operating Power (mW)	Contact Load Rating	
		5	64	3.8	405	Resistive: 1A/28Vdc	
- o o e	S172	12	400	9.0	360	Inductive: 200mA/28Vdc (320mH)	
200	S172D	26	1600	18.0	440	Lamp: 100mA/28Vdc	
						Low Level: 10 to 50 uA/10 to 50 mV	





S172D

Series S422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board surface mounting, its small size and low coil power dissipation make the S422 relay one of the most versatile ultraminiature relays available.

The Series S422D and S422DD utilize discrete diodes for coil suppression and polarity reversal protection. The Series S422 magnetic-latching relays are ideally suited for applications where power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required.

The magnetic-latching feature of the Series S422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре					
DPDT Magneti	DPDT Magnetic-Latching					
Diode (Diode Options					
D = Internal did	ode for coil					
transient suppression						
DD = Internal o	DD = Internal diode for coil					
transient supp	ression and					
polarity reversa	al protection					
Vibration	Shock					
10 g's to 500 Hz	30 g's 6 mse half-sine					

Part N	lo.	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
		5	61	3.5	Resistive: 1A/28Vdc
		6	120	4.5	Inductive: 200mA/28Vdc (320mH)
54	S422	9	280	6.8	Lamp: 100mA/28Vdc
36	S422D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
2766		18	1130	13.5	
		26	2000	18.0	
		5	48	4.5	Resistive: 1A/28Vdc
		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
54	CAOODD	9	280	7.8	Lamp: 100mA/28Vdc
36	S422DD	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
776		18	1130	14.5	
		26	2000	19.0	

Nominal Coil

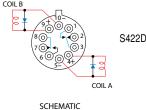
Temperature

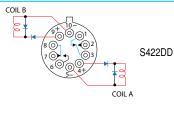
Storage: -65°C to +125°C

Operating: -55°C to +85°C

SA222

SCHEMATIC





EMATIC SCHEMATIC SCHEMATIC (Coil A Last Energized)

Series ER114 Electromechanical Relays

The Series ER114 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay. Its low profile height .275" (7 mm) and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The basic design and internal construction are similar to the standard Teledyne DPDT TO-5 relay (e.g., Series ER412).

The Series ER114D and ER114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the ER114 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the ER114 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре				Nor	ninal Coil			
DPDT Non-Latching		Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
transient suppr	ression	William		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal o	diode for coil	84	ER114	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient suppr	ression and		ER114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity reversa	polarity reversal protection			18	880	13.5	0.59	10.0	
Vibration	Shock	1 11111111		26	1560	18.0	0.89	13.0	
30 q's	75 g's 6 msec,			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	PREFE		6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	ER114DD	ED11/IDD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
Acceleration	Operating &		12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV	
50 g's	Storage:			18	880	14.5	1.1	10.0	
00 90	-65°C to +125°C			26	1560	19.0	1.4	13.0	

Series ER116C Electromechanical Relays

The ER116C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The Series ER116C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement mode MOSFET chip, which enables direct relay interfacing with most Microprocessor and IC logic families (CMOS, TTL and MOS).

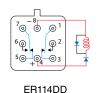
- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration

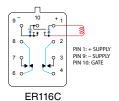
Relay	Relay Type							
DPDT Non-Lat	DPDT Non-Latching							
CMOS Feature								
Internal power N	MOSFET							
driver, Zener dic	de gate protec-							
tion, and diode coil suppression								
Vibration	Shock							
30 g's	75 g's 6 msec,							
to 3000 Hz	half-sine							
Acceleration	Temperature							
50 g's	Operating & Storage:							
	-65°C to +125°C							

			Nomina	Coil						
Part No.	Voltage	Coil Current (mA)		Operating	P.U.V (Vdc)	Contact Load Rating				
	(Vdc)	Min.	Max.	Power (mW)	(max.)					
	5	96.5	132.3	641	4.0	Resistive: 1A/28Vdc				
116C	6	60.3	83.9	462	4.9	Inductive: 200mA/28Vdc (320mH)				
ER116C	9	33.1	47.1	368	7.3	Lamp: 100mA/28Vdc				
ENTIOC	12	24.9	36.1	369	9.8	Low Level: 10 to 50 uA/10 to 50 mV				
1 11/1/11	18	16.1	24.1	368	14.6					
1 / 1/1/11	26	12.9	19.9	450	19.5					









P.U.V = Pick-Up Voltage Schematics as viewed from terminals

Series ER134 Electromechanical Relays

The ER134 sensitive Centigrid® relay retains the same features as the ER114 standard Centigrid® relay with only a minimal increase in profile height .375" (9.53 mm). Its .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, and its low profile make the ER134 relay ideal for applications where high packaging density is important.

The Series ER134D and ER134DD have internal discrete silicon diodes for coil suppression and polarity reversal protection.

The sensitive ER134 Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре			Nom	inal Coil	Contact Load Rating		
DPDT Non-Latching		Part No.	Voltage	Resistance	P.U.V		D.O.V (Vdc)	
Diode (Options		(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil		5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc
transient supp	ression	1 - 1 3 4	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal o	diode for coil	ER134	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient supp	ression and	ER134D	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity revers	al protection		18	1600	13.5	0.59	10.0	
Vibration	Shock	0 11 11 11 11	26	3200	18.0	0.89	13.0	
30 q's	75 g's 6 msec,		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	1 21/34	6	125	4.8	0.8	3.0	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	ER134DI	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
Addeleration	remperature	En 13401	12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
	Operating &		18	1600	14.5	1.1	9.0	
50 g's	Storage:	0 0	26	3200	19.0	1.3	13.0	
	-65°C to +125°C							

Series ER136C Electromechanical Relays

The sensitive ER136C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The sensitive ER136C Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mW, typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The sensitive Series ER136C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement-mode MOSFET chip that enables direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration

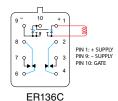
Relay	Relay Type							
DPDT Non-Latching								
CMOS Feature								
Internal power N	MOSFET							
driver, Zener dic	de gate protec-							
tion, and diode coil suppression								
Vibration	Shock							
30 g's	75 g's 6 msec,							
to 3000 Hz	half-sine							
Acceleration	Temperature							
	Operating &							
50 g's	Storage:							
	-65°C to +125°C							

			Nomina	l Coil				
Part No.	Voltage	Coil Current (mA)		Operating	P.U.V (Vdc)	Contact Load Rating		
	(Vdc)	Min.	Max.	Power (mW)	(max.)			
	5	43.0	56.0	250	4.0	Resistive: 1A/28Vdc		
The same of the sa	6	27.0	33.0	180	4.9	Inductive: 200mA/28Vdc (320mH)		
ER136C	9	17.8	26.4	203	7.3	Lamp: 100mA/28Vdc		
ENISOC	12	11.3	17.7	180	9.8	Low Level: 10 to 50 uA/10 to 50 mV		
	18	8.4	13.8	203	14.6			
11/1/1/11	26	5.8	10.2	219	19.5			









Schematics as viewed from terminals

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

Series ER411 & ER431 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the ER411 relay one of the most versatile ultraminiature relays available.

The Series ER411D and ER411DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER411T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive ER431 relay has a high resistance coil, thus requiring extremely low operating power (150 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series ER431D and ER431DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER431T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by minimizing the number of external components needed to drive the relay.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Relay Type				Nor	ninal Coil			
SPDT Non-Lat	ching	Part I	lo.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
ER411 = Stand	lard Coil	47.00		5	63	3.7	0.15	2.4	Resistive: 1A/28Vdc
ER431 = Sensi	itive Coil	37,03		6	125	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Diode C	Options		ER411	9	280	6.8	0.35	4.2	Lamp: 100mA/28Vdc
D = Internal did	ode for coil		ER411D	12	500	9.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
transient suppr	ression	16641		18	1130	13.5	0.58	8.4	
DD = Internal o	liode for coil	-111		26	2000	18.0	0.89	10.4	
transient suppr	ression and	A Section		5	50	4.5	0.15	2.4	Resistive: 1A/28Vdc
polarity reversa	al protection	200		6	98	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
T = Internal tra	nsistor drive		ER411DD	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
and coil transie	ent suppression			12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
diode		166h1		18	1130	14.5	0.58	8.4	
Vibration	Shock			26	2000	19.0	0.89	10.4	
30 g's	75 g's 6 msec,	3000		5	63	3.9	0.15	2.4	Resistive: 1A/28Vdc
to 3000 Hz	half-sine		ER411T	6	125	5.2	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature			9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc
Addeleration	Operating &			12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
50 g's	Storage:			18	1130	14.5	0.58	8.4	
55 9 5	-65°C to +125°C	•••		26	2000	19.0	0.89	10.4	5 1 11 14 (20)(1
				5	125	3.7	0.15	2.0	Resistive: 1A/28Vdc
		431 -5A	ED464	6	255	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
4 1 ② 5 ③	ED 444	83960	ER431	9	630	6.8	0.35	4.2	Lamp: 100mA/28Vdc
	ER411 ER431		ER431D	12 18	1025	9.0	0.41	5.6 8.4	Low Level: 10 to 50 uA/10 to 50 mV
3 ◎▶ ▲ ◎ 2	2.1101	/ / N		18 26	2300 4000	13.5 18.0	0.58 0.89	8.4 10.4	
		11 11 11		5	100	4.5	0.69	2.4	Resistive: 1A/28Vdc
八				6	200	5.5	0.13	2.4	Inductive: 200mA/28Vdc (320mH)
4 5 01		-5A		9	630	7.8	0.16	4.2	Lamp: 100mA/28Vdc
	ER411D ER431D	83960	ER431DD	12	1025	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV
3 ◎▶4◎2	LITTOID			18	2300	14.5	0.58	8.4	20W 20VCI. 10 to 30 d/ / 10 to 30 IIIV
				26	4000	19.0	0.89	10.4	
Л		431 -5A 06461		5	125	3.6	0.15	2.0	Resistive: 1A/28Vdc
4 5 01				6	255	4.8	0.18	2.8	Inductive: 200mA/28Vdc (320mH)
	ER411DD			9	630	7.8	0.35	4.2	Lamp: 100mA/28Vdc
3 (3) → (4) 2	ER431DD	83960	ER431T	12	1025	10.0	0.41	5.6	Low Level: 10 to 50 uA/10 to 50 mV
				18	2300	14.5	0.58	8.4	
П				26	4000	19.0	0.89	10.4	

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Schematics as viewed from terminals

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

Series ER412 & ER432 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the ER412 relay one of the most versatile ultraminiature relays available.

The Series ER412D and ER412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive ER432 relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series ER432D and ER432DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid ER432T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by minimizing the number of external components needed to drive the relay.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре				Nom	inal Coil			
DPDT Non-Latching		Part I	No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
ER412 = Stand	lard Coil	1000		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
ER432 = Sensi	itive Coil	32,63		6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode C	Options	10000	ER412	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal dic	D = Internal diode for coil		ER412D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 uA
transient suppr	ression	16641		18	880	13.5	0.59	10.0	
DD = Internal d	liode for coil	411		26	1560	18.0	0.89	13.0	
transient suppr	ression and	A Section		5	39	3.9	0.6	2.8	Resistive: 1A/28Vdc
polarity reversa	al protection	2000		6	78	5.2	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
T = Internal tra	nsistor drive		ER412DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
and coil transie	ent suppression			12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 uA
diode		16641		18	880	14.5	1.1	10.0	
Vibration	Shock	411		26	1560	19.0	1.4	13.0	
30 g's	75 g's 6 msec,	A Laborator		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
to 3000 Hz	half-sine		ER412T	6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
				9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
Acceleration	Temperature			12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 m²n	Operating & Storage:	16641		18	880	13.5	0.59	10.0	
50 g's	-65°C to +125°C	411.		26	1560	18.0	0.89	13.0	
	-03 0 10 +123 0			5	100	3.5	0.14	2.5	Resistive: 1A/28Vdc
П		43		6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
96001		0305	ER432	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc
8© ©2	ER412	2250	ER432D	12	850	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
700+403	ER432			18	1600	13.5	0.59	10.0	
		11 1 1 1 1 1		26	3300	18.0	0.89	13.0	
				5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc
**		43		6	125	4.8	8.0	3.0	Inductive: 200mA/28Vdc (320mH)
80 02	ER412D	0305 5520	ER432DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc
7 ◎ → 4 → 4 ◎ 3	ER432D		LITTOLDD	12	850	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV
60 04				18	1600	14.5	1.1	9.0	
	_	11 # 1 11		26	3300	19.0	1.3	13.0	
	9	43 -54 -530 -530 -530 -530 -530 -530 -530 -530		5	100	3.6	0.14	2.5	Resistive: 1A/28Vdc
90 01	ER412DD			6	200	4.8	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
70+4-403)	ER412DD ER432DD		ER432T	9	400	7.8	0.35	4.9	Lamp: 100mA/28Vdc
60104		2055	2117021	12	850	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
				18	1600	14.5	0.59	10.0	
	g	11 1 1 1 1 1		26	3300	19.0	0.89	13.0	

Schematics as viewed from terminals

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

ER412T

ER432T

Series 255, 256, 257, 258 Electromechanical Relays

The Series 255 is an industry-standard, half-size, latching crystal can relay. It has a wide range of switching capabilities ranging from low level to 2 amps. The Series J255/255 latching relay configuration is double-pole double-throw (DPDT), so the relay offers excellent switching density and versatility. Half-Size Crystal Can Features:

- · Low level to 2 amps
- Wide range of switching capabilities
- · Smallest relay package capable of switching 2 amps
- Modernized assembly process
- · Lead-free (gold-plated wire lead only)

- · All welded construction
- · Wire leads, gold-plated or solder-coated
- · Matched seal for superior hermeticity
- · Gold-plated contact assembly
- · Modernized assembly process
- Advanced cleaning techniques

Relay Type			Nomi	nal Coil			
DPDT Magnetic-Latching	Part No.	Voltage	Resistance		eset Voltage Vdc)	Contact Load Rating	
Vibration		(Vdc)	(Ω)	Min.	Max.		
30G, 10-2500 Hz (Sinusoidal)	255	5	45	1.0	3.8	Resistive: 2A/28Vdc	
Shock	256	6 12	63 254	1.3 2.6	4.5 9.0	Inductive: 0.75A/28Vdc (320mH) Intermediate Current: 0.1A/28Vdc	
100G, 6 msec half-sine (Specified Pulse)	257 258	26 26	1000 1000	5.2 5.2	18.0 18.0	Lamp: 0.16A/28Vdc Low Level: 10 to 50 uA/10 to 50 m\	
Temperature	255		256	0.2	257	258	
Operating & Storage: -65°C to +125°C			A1 = 0	D 85			
	SCHEMATIC (Coil X Last Energized) (Bottom View)		SCHEMATIC (Coil X Last Energized) (Bottom View)		SCHEMATIC (Coll X Last Energized) (Bottom View)	SCHEMATIC (Coll Y Last Energized) (Bottom View)	

Series ER421 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the ER421 relay one of the most versatile ultraminiature relays available.

The Series ER421D and ER421DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series ER421 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series ER421 provides a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type						
SPDT Magnetic	SPDT Magnetic-Latching					
Diode C	Options					
D = Internal dic	de for coil					
transient suppr	ession					
DD = Internal d	liode for coil					
transient suppr	ession and					
polarity reversal protection						
1	a. p. otootioi.					
Vibration	Shock					
Vibration	Shock					
Vibration 30 g's	Shock 100 g's 6 msec,					
Vibration 30 g's to 3000 Hz	Shock 100 g's 6 msec, half-sine					
Vibration 30 g's to 3000 Hz	Shock 100 g's 6 msec, half-sine Temperature Operating & Storage:					
Vibration 30 g's to 3000 Hz Acceleration	Shock 100 g's 6 msec, half-sine Temperature Operating &					

			Nominal C	oil	
	Part No.	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
۱		5	61	3.5	Resistive: 1A/28Vdc
	The state of the s	6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	ER421	9	280	6.8	Lamp: 100mA/28Vdc
	En421	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
	12.	18	1130	13.5	
		26	2000	18.0	
		5	61	3.7	Resistive: 1A/28Vdc
,		6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	ER421D	9	280	6.8	Lamp: 100mA/28Vdc
	ER421D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
1		18	1130	13.5	
		26	2000	18.0	
		5	48	4.5	Resistive: 1A/28Vdc
		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
	ER421DE	9	280	7.8	Lamp: 100mA/28Vdc
	ER42IDL	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
	1	18	1130	14.5	
		26	2000	19.0	

Series ER420 & ER422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the ER420 & ER422 relays some of the most versatile ultraminiature relays available.

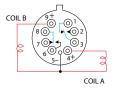
The Series ER420D/ER422D and ER420DD/ER422DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series ER420/ER422 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series ER420/ER422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

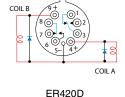
- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

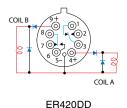
	Relay Type					
	DPDT Magnetic-Latching					
	g Options	Grounding				
	al	420 = Individua				
1	า	422 = Commor				
- 6	Options	Diode C				
	ode for coil	D = Internal dic				
Ш	ression	transient suppr				
	DD = Internal diode for coil					
	ession and	transient suppr				
	al protection	polarity reversa				
0	Shock	Vibration				
,	100 g's 6 msec,	30 g's				
	half-sine	to 3000 Hz				
	Temperature	Acceleration				
	Operating &					
	Storage:	50 g's				
ز	-65°C to +125°C					

Part No.			Nominal C	oil	
		Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
2000		5	61	3.5	Resistive: 1A/28Vdc
27.03	ER420	6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	ER422	9	280	6.8	Lamp: 100mA/28Vdc
	ER420D	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
14441	ER422D	18	1130	13.5	
411		26	2000	18.0	
1800		5	48	4.5	Resistive: 1A/28Vdc
27,03		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
000000	ER420DD	9	280	7.8	Lamp: 100mA/28Vdc
ER422DD		12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
16 h h l		18	1130	14.5	
411.		26	2000	19.0	

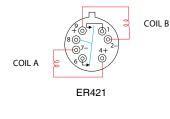


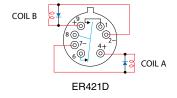
ER420

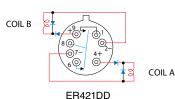


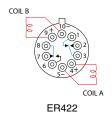


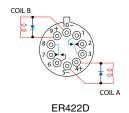
Schematics Shown with Coil A Last Energized Schematics as viewed from terminals

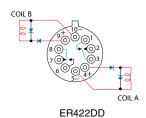












Series J114 Electromechanical Relays

The Series J114 Centigrid® relay is an ultraminiature, hermetically sealed, armature relay. Its low profile height .275" (7 mm) and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required. The basic design and internal construction are similar to the standard Teledyne DPDT TO-5 relay (e.g.,

The Series J114D and J114DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the J114 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the J114 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

- · All welded construction
- · Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- · High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре				Nom	inal Coil			
DPDT Non-Latching		Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Diode C	Options			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil			5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc
transient suppr	ression	J114 (M39016/17) J114D (M39016/18)	J114	6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
DD = Internal d	liode for coil		(M39016/17)	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc
transient suppr	ression and		J114D	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
polarity reversa	al protection		18	880	13.5	0.59	10.0		
Vibration	Shock	1 11111111		26	1560	18.0	0.89	13.0	
30 g's	75 g's 6 msec,			5	39	4.0	0.6	2.8	Resistive: 1A/28Vdc
to 3000 Hz	half-sine	Pilling		6	78	5.0	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Acceleration	Temperature	545	J114DD	9	220	7.8	0.8	5.3	Lamp: 100mA/28Vdc
Acceleration			(M39016/18)	12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 g's	Operating & Storage:			18	880	14.5	1.1	10.0	
50 g s	-65°C to +125°C			26	1560	19.0	1.4	13.0	

Series J116C Electromechanical Relays

The J116C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The Series J116C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement mode MOSFET chip, which enables direct relay interfacing with most Microprocessor and IC logic families (CMOS, TTL and MOS).

- · All welded construction
- · Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration

Relay Type									
DPDT Non-Latching									
CMOS I	CMOS Feature								
Internal power N	MOSFET								
driver, Zener dic	de gate protec-								
tion, and diode of	coil suppression								
Vibration	Shock								
30 g's	75 g's 6 msec,								
to 3000 Hz	half-sine								
Acceleration	Temperature								
50 g's	Operating & Storage: -65°C to +125°C								

P.U.V = D.O.V =

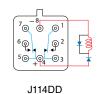
= Pick-Up Voltage	♥ [⊚ ⁵
= Drop-Out Voltage	J

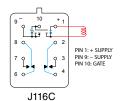
		N	lominal			
Part No.	Voltage	Coil Current (mA)		Operating	P.U.V (Vdc)	Contact Load Rating
	(Vdc)	Min.	Max.	Power (mW)	(max.)	
	5	96.5	132.3	641	4.0	Resistive: 1A/28Vdc
116C	6	60.3	83.9	462	4.9	Inductive: 200mA/28Vdc (320mH)
J116C	9	33.1	47.1	368	7.3	Lamp: 100mA/28Vdc
(M28776/6)	12	24.9	36.1	369	9.8	Low Level: 10 to 50 uA/10 to 50 mV
/ //////I	18	16.1	24.1	368	14.6	
1.1111111	26	12.9	19.9	450	19.5	





J114D





Series J134 Electromechanical Relays

The J134 sensitive Centigrid® relay retains the same features as the J114 standard Centigrid® relay with only a minimal increase in profile height .375" (9.53 mm). Its .100" (2.54 mm) grid spaced terminals, which preclude the need for spreader pads, and its low profile make the J134 relay ideal for applications where high packaging density is important.

The Series J134D and J134DD have internal discrete silicon diodes for coil suppression and polarity reversal protection.

The sensitive J134 Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре	Part No.		Nominal Coil							
DPDT Non-Lat	ching			Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating
Diode C	Options					(Vdc)	(Ω)	(Vdc) (max.)	min.	max.	
D = Internal did	ode for coil	200		5	100	3.5	0.12	2.5	Resistive: 1A/28Vdc		
transient suppr	ression	STATE OF THE PARTY	J134	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)		
DD = Internal d	liode for coil		(M39016/41)	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc		
transient suppr	ression and		J134D	12	800	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV		
polarity reversa	al protection	MTN	(M39016/42)	18	1600	13.5	0.59	10.0			
Vibration	Shock	III A MA		26	3200	18.0	0.89	13.0			
30 g's	75 q's 6 msec,	210		5	64	3.7	0.7	2.6	Resistive: 1A/28Vdc		
to 3000 Hz	half-sine	200 00 000		6	125	4.8	8.0	3.0	Inductive: 200mA/28Vdc (320mH)		
Acceleration	Temperature	97.01- 1987	J134DD	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc		
Acceleration	Operating &		(M39016/43)	12	800	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV		
50 g's	Storage:	1/17 []		18	1600	14.5	1.1	9.0			
55 95	-65°C to +125°C	JIT A IN I		26	3200	19.0	1.3	13.0			

Series J136C Electromechanical Relays

The sensitive J136C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" (2.54 mm) grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The sensitive J136C Centigrid® relay has a high resistance coil, thus requiring extremely low operating power (200 mW, typical). The advantages of reduced heat dissipation and power supply demands are a plus.

The sensitive Series J136C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement-mode MOSFET chip that enables direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

J136C

Part No.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Contact Load Rating

Resistive: 1A/28Vdc

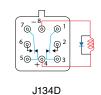
Inductive: 200mA/28Vdc (320mH)

Lamp: 100mA/28Vdc

Low Level: 10 to 50 uA/10 to 50 mV

Relay Type								
DPDT Non-Latching								
CMOS Feature								
Internal power N	MOSFET							
driver, Zener dic	de gate protec-							
tion, and diode o	coil suppression							
Vibration	Shock							
30 g's	75 g's 6 msec,							
to 3000 Hz	half-sine							
Acceleration	Temperature							
Operating 8								
50 g's	Storage:							
	-65°C to +125°C							

© 7 © 10 6 8 2 0 0 5 4 3 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	
J134	_



Nominal Coil

Max

56.0

33.0

26.4

17.7

13.8

10.2

Operating

Power (mW)

250

180

203

180

203

219

Coil Current

(mA)

Min.

43.0

27.0

17.8

11.3

8.4

5.8

Voltage

(Vdc)

5

6

9

12

18

26



P.U.V

(max.

4.0

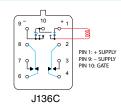
4.9

7.3

9.8

14.6

19.5



P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

Series J411 & J431 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the J411 relay one of the most versatile ultraminiature relays available.

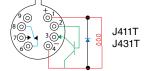
The Series J411D and J411DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J411T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive J431 relay has a high resistance coil, thus requiring extremely low operating power (150 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series J431D and J431DD relays have internal discrete silicon diodes for coil suppression and polarity

reversal protection. The hybrid J431T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре			Nominal Coil								
SPDT Non-Lat	ching	Part I	No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating			
Coil	Туре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.				
J411 = Standar	d Coil	2250		5	63	3.7	0.15	2.4	Resistive: 1A/28Vdc			
J431 = Sensitiv	/e Coil	2.62	J411	6	125	4.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)			
Diode C	Options		(M39016/7)	9	280	6.8	0.35	4.2	Lamp: 100mA/28Vdc			
D = Internal did	ode for coil		J411D	12	500	9.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV			
transient suppr	ression	14441	(M39016/23)	18	1130	13.5	0.58	8.4				
DD = Internal d	liode for coil	***		26	2000	18.0	0.89	10.4				
transient suppr	ession and	Ber Jak		5	50	4.5	0.15	2.4	Resistive: 1A/28Vdc			
polarity reversa	al protection	-		6	98	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)			
T = Internal tra	nsistor drive		J411DD	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc			
and coil transie	ent suppression		(M39016/24)	12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV			
diode		14441		18	1130	14.5	0.58	8.4				
Vibration	Shock	• • • •		26	2000	19.0	0.89	10.4	5			
30 g's	75 g's 6 msec,		300 00		5	63	3.9	0.15	2.4	Resistive: 1A/28Vdc		
to 3000 Hz	half-sine			6	125	5.2	0.18	2.8	Inductive: 200mA/28Vdc (320mH)			
Acceleration	Temperature		J411T (M28776/5)	9	280	7.8	0.35	4.2	Lamp: 100mA/28Vdc			
				(W20110/3)	12	500	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV		
	Operating &			18	1130	14.5	0.58	8.4				
50 g's	Storage:			26 5	2000 125	19.0 3.7	0.89	2.0	Resistive: 1A/28Vdc			
	-65°C to +125°C	431 -5A 06461 93960	431 -5A 06461 33960	- T. C.	- T. C.	1404	6	255	4.5	0.15	2.8	Inductive: 200mA/28Vdc (320mH)
				J431 (M39016/10)	9	630	6.8	0.16	4.2	Lamp: 100mA/28Vdc		
				33960		12	1025	9.0	0.33	5.6	Low Level: 10 to 50 uA/10 to 50 mV	
(0 5 0 5	J411								J431D (M39016/25)	18	2300	13.5
3 ◎▶ ★◎ 2	J431	111	(26	4000	18.0	0.89	10.4				
				5	100	4.5	0.15	2.4	Resistive: 1A/28Vdc			
		431		6	200	5.5	0.18	2.8	Inductive: 200mA/28Vdc (320mH)			
+		-5A	J431DD	9	630	7.8	0.35	4.2	Lamp: 100mA/28Vdc			
	J411D	83960	(M39016/26)	12	1025	10.0	0.40	5.6	Low Level: 10 to 50 uA/10 to 50 mV			
(30)402	J431D			18	2300	14.5	0.58	8.4				
				26	4000	19.0	0.89	10.4				
		- 173		5	125	3.6	0.15	2.0	Resistive: 1A/28Vdc			
+ ++	7	431		6	255	4.8	0.18	2.8	Inductive: 200mA/28Vdc (320mH)			
4 5 0 1 T	J411DD	06461	J431T	9	630	7.8	0.35	4.2	Lamp: 100mA/28Vdc			
(30)	J431DD	83960	(M28776/4)	12	1025	10.0	0.41	5.6	Low Level: 10 to 50 uA/10 to 50 mV			
3- 2/				18	2300	14.5	0.58	8.4				
				26	4000	19.0	0.89	10.4				



P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

Series J412 & J432 Electromechanical Relays

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed specifically for high-density PC board mounting, its small size and low coil power dissipation make the J412 relay one of the most versatile ultraminiature relays available.

The Series J412D and J412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

The sensitive J432 relay has a high resistance coil, thus requiring extremely low operating power (200 mw typical). The advantages of reduced heat dissipation and power supply demands are a plus. The Series J432D and J432DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid J432T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay	Туре				Non	ninal Coil				
DPDT Non-Lat	ching	Part I	No.	Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating	
Coil	Гуре			(Vdc)	(Ω)	(Vdc) (max.)	min.	max.		
J412 = Standar	d Coil	477		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc	
J432 = Sensitiv	/e Coil	3-77,03	J412	6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)	
Diode C	Options	The same of	(M39016/9) J412D (M39016/15)	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc	
D = Internal did	ode for coil			12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 uA	
transient suppr	ession	16 4 11		18	880	13.5	0.59	10.0		
DD = Internal d	liode for coil	411		26	1560	18.0	0.89	13.0		
transient suppr	ession and	49.50		5	39	3.9	0.6	2.8	Resistive: 1A/28Vdc	
polarity reversa	al protection	200		6	78	5.2	0.7	3.4	Inductive: 200mA/28Vdc (320mH)	
T = Internal tra	nsistor drive		J412DD	9	220	7.8	8.0	5.3	Lamp: 100mA/28Vdc	
and coil transie	ent suppression		(M39016/20)	12	390	10.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 uA	
diode		/hhhl	16 h h		18	880	14.5	1.1	10.0	
Vibration	Shock	-111		26	1560	19.0	1.4	13.0		
30 g's	75 g's 6 msec,	Section .		5	50	3.5	0.14	2.3	Resistive: 1A/28Vdc	
to 3000 Hz	half-sine			6	98	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)	
Acceleration	Temperature		J412T	9	220	6.8	0.35	4.9	Lamp: 100mA/28Vdc	
Acceleration	remperature		(M28776/1)	12	390	9.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV	
	Operating &	14441		18	880	13.5	0.59	10.0		
50 g's	Storage:	•••		26	1560	18.0	0.89	13.0		
	-65°C to +125°C			5	100	3.5	0.14	2.5	Resistive: 1A/28Vdc	
П		-5A	J432 (M39016/11)	6	200	4.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)	
96001		0305 5520	(,	9	400	6.8	0.35	4.9	Lamp: 100mA/28Vdc	
(80) - 02	J412		J432D (M39016/16)	12 18	850 1600	9.0 13.5	0.41 0.59	6.5 10.0	Low Level: 10 to 50 uA/10 to 50 mV	
7004	J432	11/11/1	(10139010/10)	26	3300	18.0	0.89	13.0		
		11 1 1 1 1		5	64	3.7	0.69	2.6	Resistive: 1A/28Vdc	
		41		6	125	4.8	0.7	3.0	Inductive: 200mA/28Vdc (320mH)	
90 01		-5A	140000	9	400	8.0	0.9	4.5	Lamp: 100mA/28Vdc	
(8 <u>0</u> <u>0</u> 2)	J412D	5520	J432DD (M39016/21)	12	850	11.0	1.0	5.8	Low Level: 10 to 50 uA/10 to 50 mV	
(6) LO4	J432D			18	1600	14.5	1.1	9.0	2011 201011 10 10 00 01 11 10 10 00 1111	
				26	3300	19.0	1.3	13.0		
	7	(60)		5	100	3.6	0.14	2.5	Resistive: 1A/28Vdc	
	3	43		6	200	4.8	0.18	3.2	Inductive: 200mA/28Vdc (320mH)	
80 02 T	J412DD	-5A 0305	J432T	9	400	7.8	0.35	4.9	Lamp: 100mA/28Vdc	
70+4-403/ 60-04	J432DD	5520	(M28776/3)	12	850	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV	
				18	1600	14.5	0.59	10.0		
	7			26	3300	19.0	0.89	13.0		

Schematics as viewed from terminals

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

.I412T

J432T

Series J255 Electromechanical Relays

The Series J255 is an industry-standard, half-size, latching crystal can relay. It has a wide range of switching capabilities ranging from low level to 2 amps. The Series J255 latching relay configuration is double-pole double-throw (DPDT), so the relay offers excellent switching density and versatility.

Half-Size Crystal Can Features:

· Low level to 2 amps

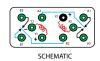
Operating & Storage: -65°C to +125°C

- Wide range of switching capabilities
- · Smallest relay package capable of switching 2 amps
- Modernized assembly process
- · Qualified to MIL-PRF39016/45
- · Lead-free (gold-plated wire lead only)

- · All welded construction
- · Wire leads, gold-plated or solder-coated
- · Matched seal for superior hermeticity
- · Gold-plated contact assembly
- · Modernized assembly process
- · Advanced cleaning techniques

Relay Type			Nomi	nal Coil		
DPDT Magnetic-Latching	Part No.	Voltage	Resistance		set Voltage (dc)	Contact Load Rating
Vibration		(Vdc)	(Ω)	Min.	Max.	
30G, 10-2500 Hz				WIII.	Wax.	
, ·	J255	5	45	1.0	3.8	Resistive: 2A/28Vdc
(Sinusoidal)		6	63	1.3	4.5	Inductive: 0.75A/28Vdc (320mH)
Shock		12	254	2.6	9.0	Intermediate Current: 0.1A/28Vdc
100G, 6 msec half-sine	(M39016/45)					
(Specified Pulse)		26	1000	5.2	18.0	Lamp: 0.16A/28Vdc
(Specified Pulse)						Low Level: 10 to 50 uA/10 to 50 mV
Temperature						

J255



Series J421 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the J421 relay one of the most versatile ultraminiature relays available.

The Series J421D and J421DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series J421 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series J421 provides a "memory" capability, since the relays will not reset upon removal of coil power.

- All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

	Type				
SPDT Magnetic-Latching					
Diode C	Options				
D = Internal did	ode for coil				
transient suppr	ression				
DD = Internal o	liode for coil				
transient suppression and					
polarity reversal protection					
Vibration	Shock				
30 g's	100 g's 6 msec,				
to 3000 Hz	half-sine				
Acceleration	Temperature				
	Operating &				
	Storage:				
50 g's	-65°C to +125°C				

*See Schematics	on	Page	27
See Schematics	on	Page	27

			Nominal C	oil	
	Part No.	Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
		5	61	3.5	Resistive: 1A/28Vdc
		6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	J421	9	280	6.8	Lamp: 100mA/28Vdc
	(M39016/8)	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
	1	18	1130	13.5	
		26	2000	18.0	
		5	61	3.7	Resistive: 1A/28Vdc
,		6	120	4.5	Inductive: 200mA/28Vdc (320mH)
	J421D	9	280	6.8	Lamp: 100mA/28Vdc
	(M39016/27)	12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
	123	18	1130	13.5	
		26	2000	18.0	
;		5	48	4.5	Resistive: 1A/28Vdc
		6	97	5.5	Inductive: 200mA/28Vdc (320mH)
	J421DD	9	280	7.8	Lamp: 100mA/28Vdc
	(M39016/28)	12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
	1	18	1130	14.5	
		26	2000	19.0	

Series J420 & J422 Electromechanical Relays

The magnetic-latching TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the J420 & J422 relays some of the most versatile ultraminiature relays available.

The Series J420D/J422D and J420DD/J422DD utilize discrete silicon diodes for coil suppression and polarity reversal protection.

The Series J420/J422 magnetic-latching relays are ideally suited for applications where coil power dissipation must be minimized. The relays can be operated with a short duration pulse. After the contacts have transferred, no external holding power is required. The magnetic-latching feature of the Series J420/J422 relays provide a "memory" capability, since the relays will not reset upon removal of coil power.

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration

COIL A

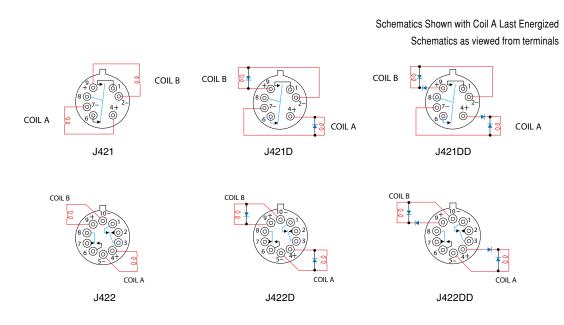
J420DD

 Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

J422 relays provi	ide a "memory" ca	apability, since t	the relays wi	ll not reset	upon removal	of coil power.	
Relay Type DPDT Magnetic-Latching					Nominal C	oil	
		Part No.		Voltage (Vdc)	Resistance (Ω)	Set & Reset Voltage (Vdc)	Contact Load Rating
Grounding	g Options		1400	5	61	3.5	Resistive: 1A/28Vdc
J420 = Individu	ıal	Section 1	J420 (M39016/12)				
J422 = Commo	on	-	(M39016/12) J422 (M39016/12) J420D (M39016/29) J422D (M39016/29)	6	120	4.5	Inductive: 200mA/28Vdc (320mH)
Diode C	Options			9	280	6.8	Lamp: 100mA/28Vdc
D = Internal did	•			12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV
transient suppr		lhhhi		18	1130	13.5	
DD = Internal o				26	2000	18.0	
		450		5	48	4.5	Resistive: 1A/28Vdc
transient suppr		J420DD (M39016/30)	6	97	5.5	Inductive: 200mA/28Vdc (320mH)	
polarity reversa			(M39016/30)	9	280	7.8	Lamp: 100mA/28Vdc
Vibration	Shock	(12	500	10.0	Low Level: 10 to 50 uA/10 to 50 mV
30 g's	100 g's 6 msec,	THE RESERVE	J422DD (M39016/30)	18	1130	14.5	2011 201011 10 10 00 01 11 10 10 00 1111
to 3000 Hz	half-sine	alli.	(,	26	2000	19.0	
Acceleration	Temperature			20	2000	10.0	
Operating & Storage: -65°C to +125°C		COIL B			COIL B	9+ 0 01 80 2	COIL B $0 - 0$
		€ \7€ 6	© 0 3 5 5 4 5 5 4 5 5 5 6 5 6 6 6 6 6 6 6 6 6	3		7 🔘 4 🔘 3	7000

COIL A

J420



J420D

COIL A

HIGH-PERFORMANCE RELAYS

Series 412H, 422H & 432H Electromechanical Relays - High Temperature

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, these TO-5 relays are some of the most versatile ultraminiature relays available because of their small size and low coil power dissipation.

The H Series high-temperature TO-5 relays are designed for reliable operation in elevated ambient temperatures up to 200°C. Special material selection and processing provide assurance of freedom from contact contamination and mechanical malfunctioning that might otherwise be caused by ultra high ambient temperature conditions.

- Typical applications:
 - · Oil exploration (down-hole) instrumentation
 - High-Temperature industrial and process control instrumentation

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type				Nom	inal Coil			
412H = DPDT Non-Latching	Part No.		Voltage	Resistance	P.U.V	D.O.V	(Vdc)	Contact Load Rating
432H = DPDT Non-Latching			(Vdc)	(Ω)	(Vdc) (max.)	min. max.		
422H = DPDT Magnetic-	20-35		5	50	4.7	0.14	2.4	Resistive: 1A/28Vdc
Latching	412H-1 0H 0 71 36 26 0		6	98	5.9	0.18	3.4	Inductive: 200mA/28Vdc (320mH)
Coil Type		44011	9	220	9.0	0.35	5.1	Lamp: 100mA/28Vdc
412H = Standard Coil		412H	12	390	11.9	0.41	6.8	Low Level: 10 to 50 uA/10 to 50 mV
422H = Standard Coil	/////		18	880	17.8	0.59	10.2	
432H = Sensitive Coil	11111		26	1560	24.0	0.89	13.5	
Vibration			5	100	4.7	0.14	2.4	Resistive: 1A/28Vdc
30 g's to 3000 Hz	432H -12		6	200	5.9	0.18	3.4	Inductive: 200mA/28Vdc (320mH)
Shock	08 08 36 4	432H	9	400	9.0	0.35	5.1	Lamp: 100mA/28Vdc
412H = 75 g's 6 msec, half-sine		432 12	12	850	11.9	0.41	6.8	Low Level: 10 to 50 uA/10 to 50 mV
432H = 75 g's 6 msec, half-sine	1118		18	1600	17.8	0.59	10.2	
422H = 100 q's	/B H/M		26	3300	24.0	0.89	13.5	

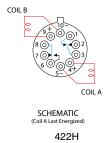
	Doub No.		Nominal C	oil			
Part No.		Voltage (Vdc)	9		Contact Load Rating		
		5	61	4.7	Resistive: 1A/28Vdc		
422H-5 08091	6	120	5.9	Inductive: 200mA/28Vdc (320mH)			
34328	422H	9	280	9.0	Lamp: 100mA/28Vdc		
MAIN	42211	12	500	11.9	Low Level: 10 to 50 uA/10 to 50 mV		
MAN		18	1130	17.8			
JULIA 1414		26	2000	24.0			



Schematics as viewed from terminals

Acceleration
50 g's
Temperature
Operating & Storage:
-65°C to +200°C

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage 412H 432H



HIGH-PERFORMANCE RELAYS

Series 412K & 422K Electromechanical Relays - High Shock

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed for high-density PC board mounting, its small size and low coil power dissipation make the TO-5 relay one of the most versatile subminiature relays available.

The K Series high-shock TO-5 relays are designed to withstand shock levels up to 4000 g's, .5 msec duration. Special material selection and construction details provide assurance that critical elements of the relay structure and mechanism will not be permanently displaced or damaged as a result of extremely high g level shocks.

Typical applications:

- · Commercial avionics aircraft control
- · Commercial aircraft control systems
- Transportation systems (rail/truck)

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

			Non	ninal Coil			Contact Load Rating	
Part No.		Voltage	Resistance	P.U.V	D.O.V (Vdc)		Contact Load Rating	
		(Vdc)	(Ω)	(Vdc) (max.)	min.	max.		
ALC: N		5	50	4.3	0.14	2.5	Resistive: 1A/28Vdc	
43.0% = 00	412K	6	80	5.2	0.18	3.2	Inductive: 200mA/28Vdc (320mH)	
95277		9	160	7.6	0.35	4.9	Lamp: 100mA/28Vdc	
		12	300	10.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV	
11111		18	600	14.3	0.59	10.0		
		26	1350	21.0	0.89	13.0		

			Nominal C	oil			
Part No.		Voltage (Vdc) Resistance (Ω) Set & Reset Voltage (Vdc)			Contact Load Rating		
THE PARTY		5	61	3.5	Resistive: 1A/28Vdc		
73K-12 7171 7626	422K	6	120	4.5	Inductive: 200mA/28Vdc (320mH)		
21650		9	280	6.8	Lamp: 100mA/28Vdc		
MIN		12	500	9.0	Low Level: 10 to 50 uA/10 to 50 mV		
ЛІІВ		18	1130	13.5			
		26	2000	18.0			

Relay Type
412K = DPDT Non-Latching
422K = DPDT Magnetic-
Latching
Vibration
30 g's to 3000 Hz
Shock
412K = 75 g's 6 msec, half-sine
4000 g's, 0.5 msec axia plane, half-sine
1000 g's, 0.5 msec side
planes, half-sine
422K = 100 g's 6 msec, half-sine
2100 g's, 0.5 msec axial

planes, half-sine

Acceleration

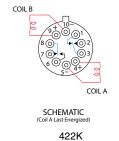
50 g's

plane, half-sine 750 g's, 0.5 msec side

Temperature

Operating & Storage: -65°C to +125°C





Schematics as viewed from terminals
P.U.V = Pick-Up Voltage
D.O.V = Drop-Out Voltage

HIGH-PERFORMANCE RELAYS

Series 412V & 432V Electromechanical Relays - High Vibration

The 412V and 432V TO-5 relays, originally conceived and developed by Teledyne, have become the industry standards for low level switching from dry circuit to 1 ampere in high-vibration environments. Designed for high-density PC board mounting, these TO-5 relays are some of the most versatile ultraminiature relay available because of their small size and low coil power dissipation.

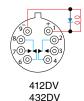
The V Series high-vibration relays are designed to withstand vibration levels of 250 to 380 g's at the frequencies noted, when tested on a resonant beam for 10 to 20 seconds, in the axis parallel to contact motion (x-axis), or 100 g's 10-2000 Hz for 20 minutes in the x-axis. A unique magnetic circuit prevents contact opening (chatter) in excess of 10 microseconds under vibration or shock conditions.

- Typical applications:
 - Avionics aircraft controlAircraft control systems
 - Transportation systems (rail/truck)

- · All welded construction
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity
- High force/mass ratio for resistance to shock and vibration
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities

Relay Type	Part No.		Nominal Coil					
DPDT Non-Latching			Voltage R (Vdc)	Resistance (Ω)	P.U.V (Vdc) (max.)	D.O.V (Vdc)		Contact Load Rating
Coil Type						min.	max.	
412V = Standard Coil	SAU	412V 412DV	5	50	4.6	0.14	2.3	Resistive: 1A/28Vdc
432V = Sensitive Coil	97903		6	70	5.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
Diode Options	20540		9	155	8.2	0.35	4.9	Lamp: 100mA/28Vdc
D = Internal diode for coil	11//		12	235	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
transient suppression	W/		18	610	16.5	0.59	10.0	
DD = Internal diode for coil	HAI		26	1130	22.0	0.89	13.0	
transient suppression and	WAS I	412DDV	5	33	4.6	0.6	2.8	Resistive: 1A/28Vdc
polarity reversal protection	97903		6	44	5.5	0.7	3.4	Inductive: 200mA/28Vdc (320mH)
Vibration	30540		9	125	8.2	8.0	5.3	Lamp: 100mA/28Vdc
250 g's at 140 ±5 Hz	1111		12	215	11.0	0.9	6.5	Low Level: 10 to 50 uA/10 to 50 mV
350 g's at 170 ±5 Hz	· · · · · · · · · · · · · · · · · · ·		18	470	16.5	1.1	10.0	
380 g's at 200 ±5 Hz	1000		26	1050	22.0	1.4	13.0	
Shock	Bank.	432V	5	80	4.6	0.14	2.5	Resistive: 1A/28Vdc
	6320		6	120	5.5	0.18	3.2	Inductive: 200mA/28Vdc (320mH)
150 g's 11 msec, half-sine	16E3+1		9	240	8.2	0.35	4.9	Lamp: 100mA/28Vdc
Acceleration	/1111	432DV	12	480	11.0	0.41	6.5	Low Level: 10 to 50 uA/10 to 50 mV
50 g's	//////		18	950	16.5	0.59	10.0	
Temperature	7 V V I I		26	1900	22.0	0.89	13.0	







Schematics as viewed from terminals

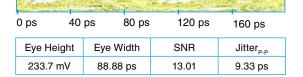
Operating & Storage: -65°C to +125°C

P.U.V = Pick-Up Voltage D.O.V = Drop-Out Voltage

-130 mV

SERIES RF100

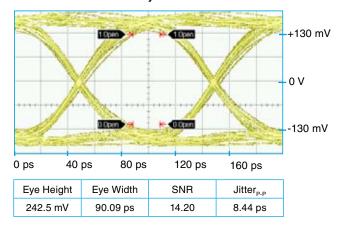
Normally Closed +130 mV



Normally Open +130 mV 0 V R p-p -130 mV 120 ps 0 ps 40 ps 80 ps 160 ps Eye Width SNR Eye Height Jitter_{P-P} 217.1 mV 88.05 ps 11.55 8.44 ps

SERIES GRF100

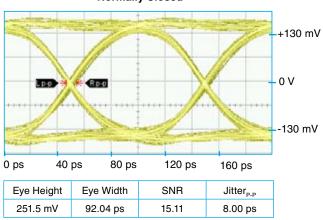
Normally Closed



Normally Open 1 Oper +130 mV 0 V 0 Open 0 Open -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 263.6 mV 87.29 ps 20.23 9.78 ps

SERIES SGRF100

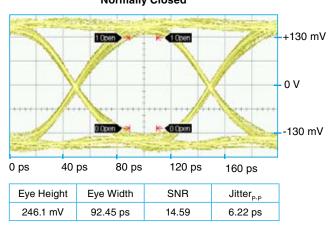
Normally Closed



Normally Open +130 mV 0 V Rp-p L p-0 -130 mV 40 ps 80 ps 0 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P} 261.2 mV 87.64 ps 18.20 8.44 ps

SERIES GRF172

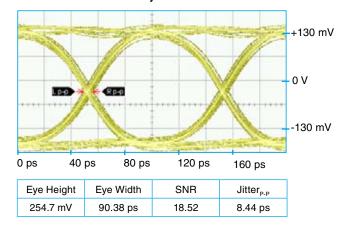
Normally Closed

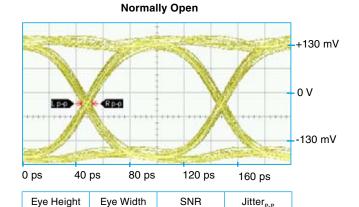


Normally Open 1 Open +130 mV 0 V -130 mV 0 Open 0 ps 40 ps 80 ps 120 ps 160 ps Eye Width Eye Height SNR Jitter_{P-P} 268.2 mV 90.87 ps 7.56 21.62

SERIES RF300/RF303

Normally Closed



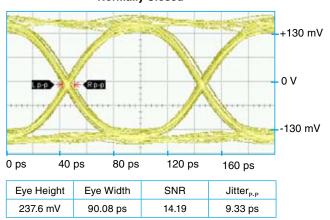


16.84

8.00 ps

SERIES GRF300/GRF303

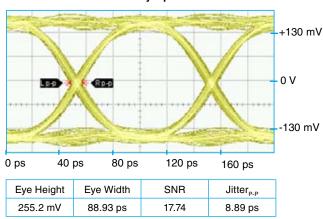
Normally Closed



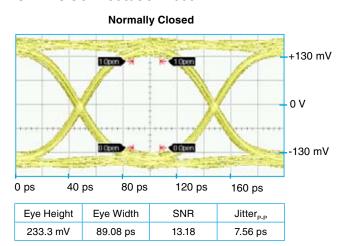
Normally Open

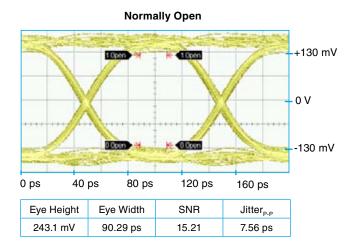
88.21 ps

250.9 mV

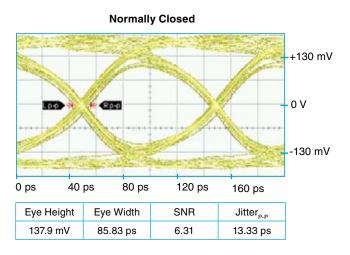


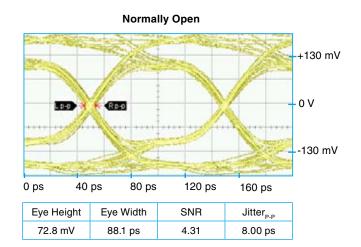
SERIES SGRF300/SGRF303



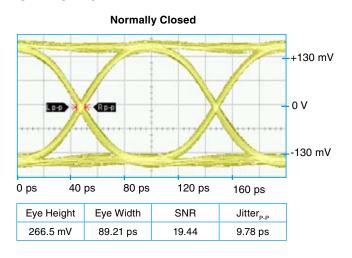


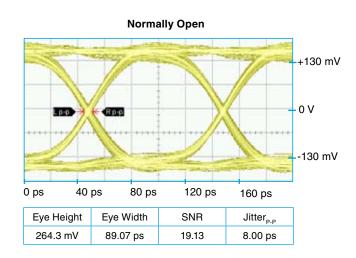
SERIES SRF300/SRF303





SERIES RF312



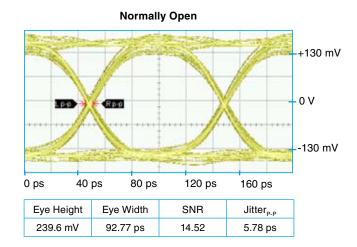


SERIES GRF312

Normally Closed +130 mV 0 V -130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{p.p}

20.75

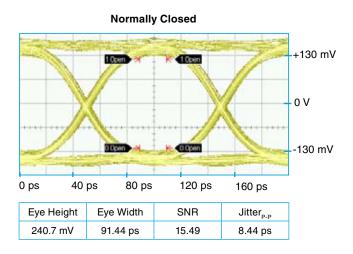
6.22 ps

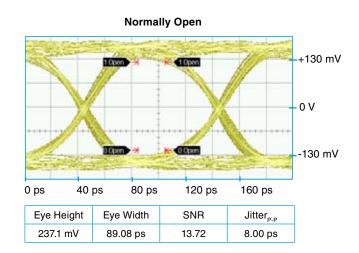


SERIES SGRF312

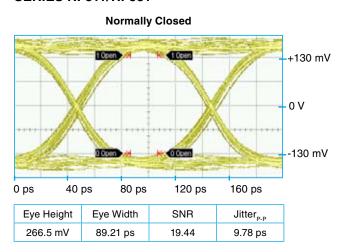
91.09 ps

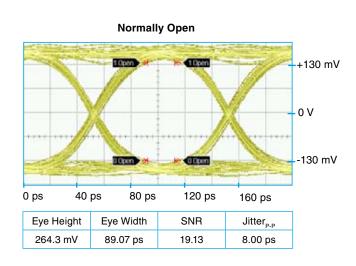
266.5 mV



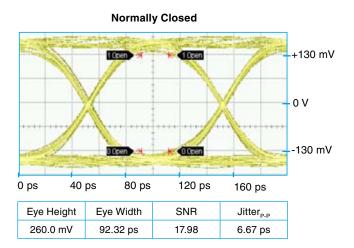


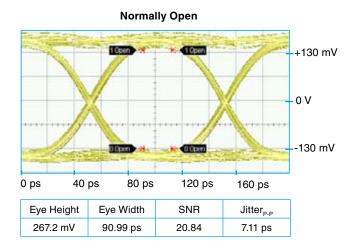
SERIES RF311/RF331



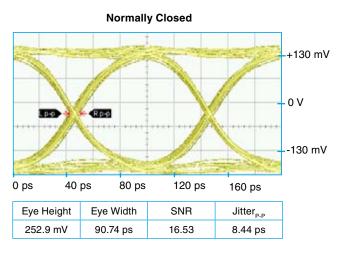


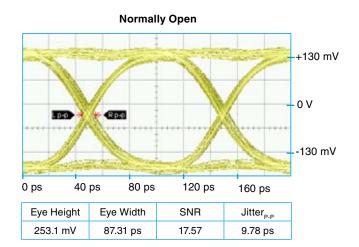
SERIES GRF311



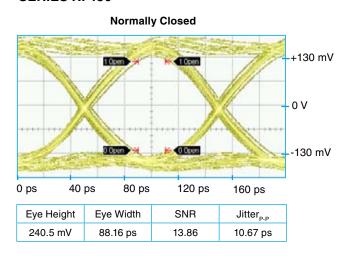


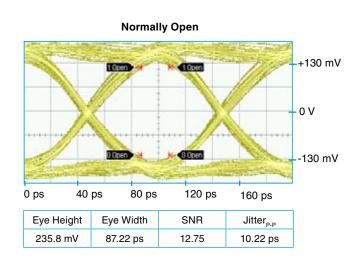
SERIES GRF342



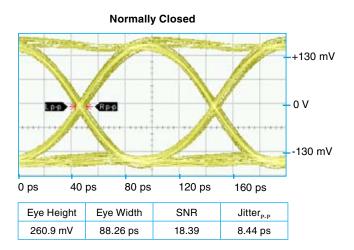


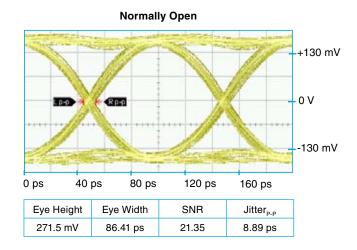
SERIES RF180



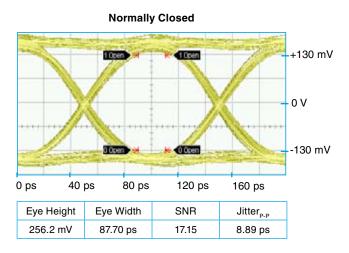


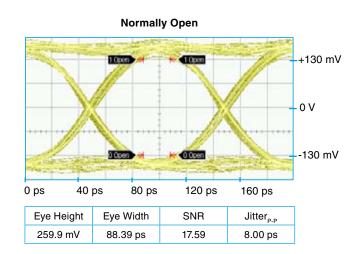
SERIES RF341



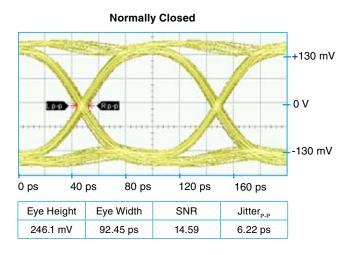


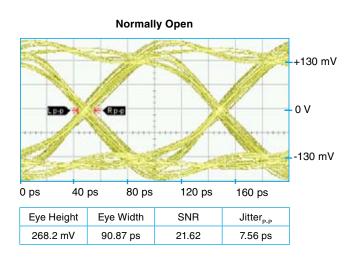
SERIES GRF341



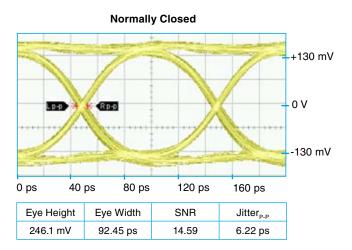


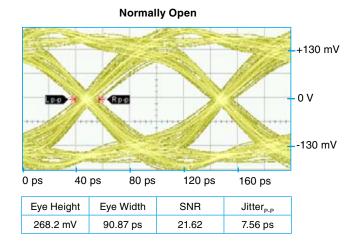
SERIES RF310/RF313



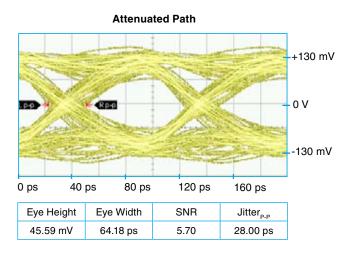


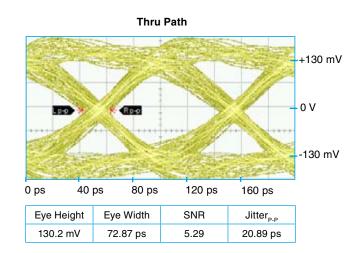
SERIES RF320/RF323



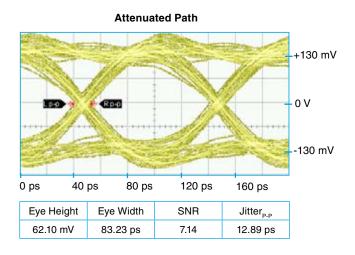


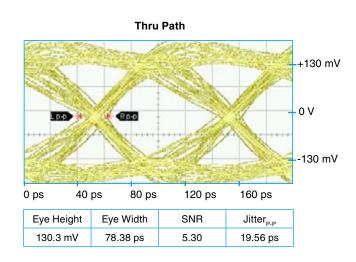
SERIES A150





SERIES GA150



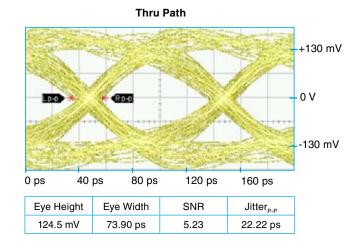


SERIES A152

Attenuated Path -+130 mV 0 ps 40 ps 80 ps 120 ps 160 ps Eye Height Eye Width SNR Jitter_{P-P}

5.57

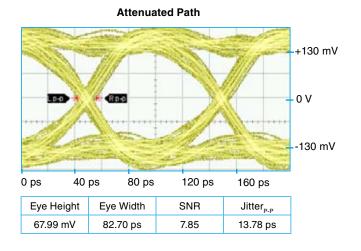
18.67 ps

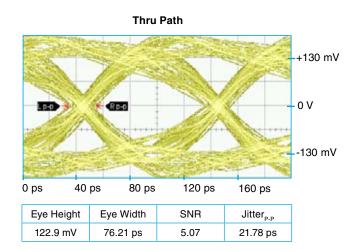


SERIES GA152

45.10 mV

78.94 ps





PATTERN GENERATOR SETTINGS

10 Gbps Random Pulse Pattern Generator 2³¹ - 1 PRBS signal PRBS output of 300mV_{P.P.} (nominal) RF PCB effect (negligible) not removed from measurement Data shown is typical of both poles

RoHS and REACH CERTIFICATE OF COMPLIANCE

RoHS

It is hereby stated and certified that Teledyne Relays complies with the Restrictions on Hazardous Substances (RoHS) Directives to the extent herein:

Teledyne Relays does <u>not</u> use any of the Restricted Substances specified by the RoHS Directives (listed below) as components in TO-5 and Centigrid® Electromechanical Relay products, nor are these substances employed during any electromechanical relay manufacturing process:

Lead
Mercury
Cadmium
Hexavalent Chromium
Polybrominated Biphenyls (PBB's)
Polybrominated Diphenyl Ethers (PBDE's)

However, upon request from the Customer, relay leads may be coated with <u>solder</u>, which contains 60% tin and 40% lead.

REACH

It is hereby stated and certified that Teledyne Relays complies with the Registration Evaluation Authorization and Restriction of Chemicals (REACH) Directives to the extent stated herein:

Teledyne Relays is a manufacturer of articles. Teledyne Relays has taken the initiative to review the (39) substances that are under consideration for treatment as Substances of Very High Concern (SVHC) candidates. Teledyne Relays confirmed that our relays do not contain any of the listed substances in concentration >0.1% weight per supplied article, substance or preparation weight.



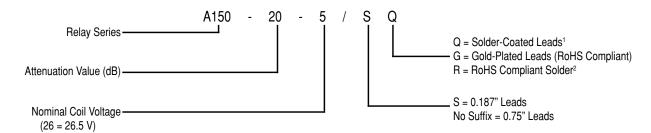


A Teledyne Technologies Company

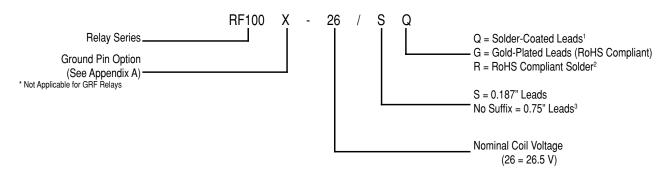
For Additional Information please E-Mail us at: relays@teledyne.com

APPENDIX: TELEDYNE RELAYS PART NUMBERING SYSTEM

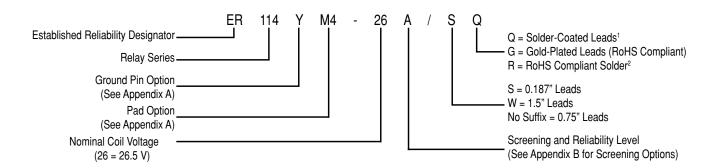
RF Attenuator Relays



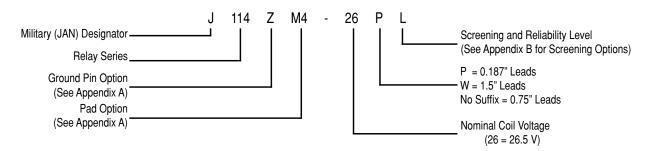
RF Relays (Except Attenuator Relays)



T²R Established Reliability Relays



Military Qualified (JAN) Relays



General Note: Parts ordered without suffix may be supplied with Solder-Coated or Gold-Plated leads

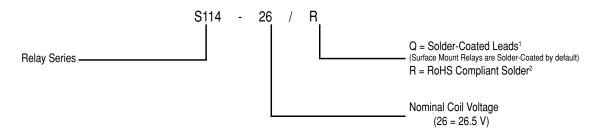
¹ Parts ordered with Solder-Coated leads will have (Sn60/Pb40)

² Parts ordered with RoHS Solder-Coated leads will have (Sn99.3/Cu0.7)

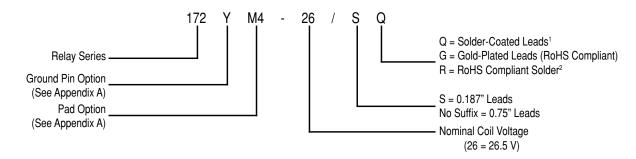
³ Not Applicable to GRF relays

APPENDIX: TELEDYNE RELAYS PART NUMBERING SYSTEM

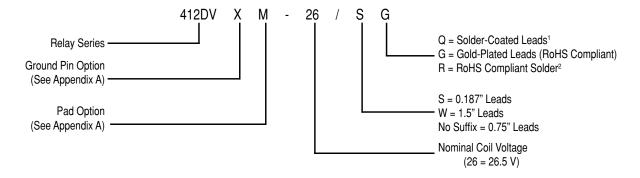
Commercial Surface Mount Relays



Commercial Relays, (Except Surface Mount Relays)



High Performance Relays



General Note: Parts ordered without suffix may be supplied with Solder-Coated or Gold-Plated leads.

- 1 Parts ordered with Solder-Coated leads will have (Sn60/Pb40)
- 2 Parts ordered with RoHS Solder-Coated leads will have (Sn99.3/Cu0.7)

If you don't see what you're looking for in this Selection Guide, contact us!

APPENDIX: Spacer Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
Ø.150 [3.81] (REF) (ROP)		ER412, ER412D, ER412DD	.295 (7.49)
	Dim H MAX	712, 712D, 712TN, RF300, RF310, RF320	.300 (7.62)
		ER420, ER422D, ER420DD, 421, ER421D, ER421DD, ER422, ER422D, ER422DD, 722, 722D, RF341	.305 (7.75)
		ER431T, ER432T, ER432, ER432D, ER432DD	.400 (10.16)
		732, 732D, 732TN, RF303, RF313, RF323	.410 (10.41)
"M4" Pad for TO-5		RF312	.350 (8.89)
П	Ţ	ER411, ER411D, ER411DD, ER411T	.295 (7.49)
	Dim H MAX	ER431, ER431D, ER431DD	.400 (10.16)
	<u> </u>	RF311	.300 (7.62)
"M4" Pad for TO-5		RF331	.410 (10.41)
		172, 172D	.305 (7.75)
	Dim H MAX	ER114, ER114D, ER114DD, J114, J114D, J114DD	.300 (7.62)
		ER134, ER134D, ER134DD, J134, J134D, J134DD	.400 (10.16)
		RF100	.315 (8.00)
"M4" Pad for Centigrid®	ШШШ	RF103	.420 (10.67)
.156 [3.96] (REF) O O O O		122C, A152	.320 (8.13)
	Dim H MAX	ER116C, J116C	.300 (7.62)
		ER136C, J136C	.400 (10.16)
		RF180	.325 (8.25)
"M9" Pad for Centigrid®	יי יי יי	A150	.305 (7.75)

Notes:

- 1. Spacer pad material: Polyester film.
- To specify an "M4" or "M9" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is \pm .010" (.25 mm).
- 5. Add 10 m Ω to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

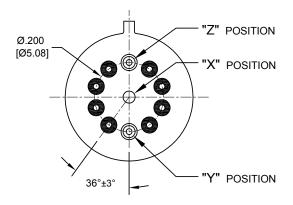
APPENDIX: Spreader Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
.150 [3.81] .370 [9.4] MAX SQ .100 [2.54]	1	ER411T, J411T, ER412, ER412D ER412DD, J412, J412D, J412DD ER412T, J412T	.388 (9.86)
	Dim H MAX .014 [0.36] (REF) .370 [9.4] MIN	712, 712D, 712TN	.393 (9.99)
		ER431T, J431T, ER432, ER432D ER432DD, J432, J432D, J432DD ER432T, J432T	.493 (12.52)
(7.02)		732, 732D, 732TN	.503 (12.78)
"M" Pad <u>5/ 6/</u>		ER420, J420, ER420D, J420D ER420DD, J420DD, ER421, J421 ER421D, J421D, ER421DD J422D, ER422DD, J422DD, 722	.398 (10.11)
390 [9.91] SQ .100 [2.54] .150 [3.81] .7.62]	Dim H MAX .130 [3.3]	ER411T ER412, ER412D, ER412DD J412, J412D, J412DD	.441 (11.20)
		712, 712D	.451 (11.46)
		ER421, ER421D, ER421DD 722, 732D	.451 (11.46)
		ER431T ER432, ER432D, ER432DD	.546 (13.87)
"M2" Pad <u>7</u> / <u>8</u> /		732, 732D	.556 (14.12)
.370 [9.4] MAX SQ .100 [2.54] .150 [3.81]	Dim H MAX .014 [0.36] (REF)	ER411, ER411D, ER411DD, ER411TX ER412X, ER412DX, ER412DDX ER412TX	.388 (9.86)
		712X, 712DX, 712TNX	.393 (9.99)
		ER420X, ER420DX, ER420DDX ER421X, ER421DX, ER421DDX ER422X, ER422DX ER422DDX, 722X, 722DDX	.398 (10.11)
		ER431, ER431D, ER431DD ER431TX ER432X, ER432DX, ER432DDX ER432TX	.493 (12.52)
"M3" Pad <u>5</u> / <u>6</u> / <u>9</u> /		732X, 732DX, 732TNX	.503 (12.78)

Notes:

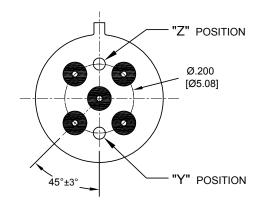
- 1. Spreader pad material: Diallyl Phthalate.
- 2. To specify an "M", "M2" or "M3" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is \pm .010" (0.25 mm).
- $\underline{5}$ /. Add 25 m Ω to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.
- $\underline{\textit{7}}\slash.$ Add 50 m Ω to the contact resistance shown in the datasheet.
- 8/. Add 0.025 oz (0.71 g) to the weight of the relay assembly shown in the datasheet.
- 9/. M3 pad to be used only when the relay has a center pin (e.g. ER411M3-12A, 722XM3-26.)

APPENDIX: Ground Pin Positions



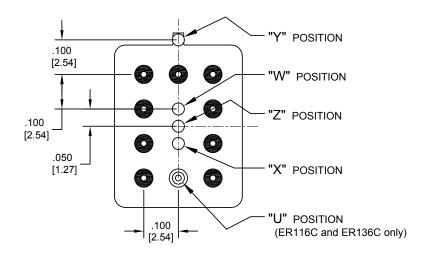
TO-5 Relays:

ER411T, ER412, ER412T, ER420, ER421, ER422, ER431T, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF341, RF312, RF310, RF313, RF320, RF323



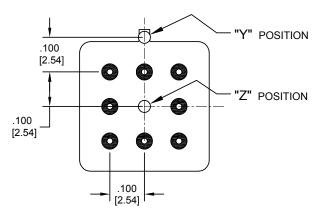
TO-5 Relays:

ER411, ER431, RF311, RF331



Centigrid® Relays:

RF180, ER116C, 122C, ER136C



Centigrid® Relays:

RF100, RF103, ER114, ER134, 172

- Indicates ground pin position
- Indicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type

NOTES

- 1. Terminal views shown
- 2. Dimensions are in inches (mm)
- 3. Tolerances: ± .010 (±.25) unless otherwise specified
- 4. Ground pin positions are within .015 (0.38) dia. of true position 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
- 6. Lead dia. 0.017 (0.43) nom.

APPENDIX: Teledyne Relays T²R Program

Teledyne Relays' The program was developed to provide the JAN relay user an alternate means of specifying and procuring established reliability relays. The form, fit and function of a The relay is the same as that of its JAN counterpart. The program requirements differ in certain regimens/tests found in both MIL-PRF-28776 and MIL-PRF-39016 that add cost but no value to the relay.

This program parallels the military specifications in most aspects. The components that make up such a program are intricate and varied. Furthermore, there are additional options of high value for design, manufacturability and operation of high reliability assemblies. The following page presents a table that compares the 100% screening performed on JAN relays and TPP relays prior to shipment.

Other significant highlights of the **T** program include:

- Two unique screening levels
- The ability to define lead finish
- Spacer pad options which may not be available in military specifications
- Ground pin options which may not be available in military specifications
- · Reduced lead time
- Reduced cost

The program is fully defined for both general product requirements and detailed product requirements in the following Teledyne Relays specifications:

TR-R-1 TR-STD-1 TR-STD-2 TR-ERL-1 TR-R-1/XXX TR Supplement

Copies of these documents are available from Teledyne Relays. We suggest that users check with Teledyne Relays from time to time to assure that they have the latest issue.

Can't Find What You Need?

Check out our full line of relays and switches. Order literature online at http://www.teledynerelays.com/lit-request.asp







APPENDIX: Teledyne Relays T²R Program

	Screening Levels				
INSPECTION	TE A Level 1.5%/10K Cycles	<i>T</i> ⊮ B Level .75%/10K Cycles	JAN L Level 3%/10K Cycles	JAN M Level 1%/10K Cycles	
Subgroup 1					
Screening, Internal Moisture AQL ¹	V	✓	✓	V	
Vibration (Sinusoidal) AQL ¹			√		
Vibration (Sinusoidal) 100%		✓		✓	
Screening, Burn-In (Hybrids only)			V	✓	
Screening, Run-In (Room Temperature)	V				
Screening, Run-In (+125°C and -65°C)		✓	✓	✓	
Subgroup 2					
Coil Resistance or Coil Current	V	V	V	V	
Insulation Resistance	V	✓	✓	✓	
Dielectric Withstanding Voltage	V	v	✓	✓	
Static Contact Resistance	V	✓	✓	✓	
Pickup and Dropout or Set and Reset Voltage	V	V	V	V	
Operate and Release or Set and Reset Time	V	✓	✓	✓	
Hold Voltage			✓	✓	
Turn-On and Turn-Off Time (Hybrids only)	V	✓	✓	✓	
Contact Bounce Time	V		✓		
Contact Stabilization Time		✓		✓	
Turn-On Current (T Hybrids only)	V	✓	✓	✓	
Turn-On Voltage (C Hybrids only)	V	v	✓	✓	
Turn-Off Voltage (Hybrids only)	V	✓	✓	✓	
Coil Transient Suppression (D, DD and Hybrids only)	V	V	V	V	
Diode Blocking Integrity (DD only)	V	✓	✓	✓	
Zener Voltage (C Hybrid only)	V	✓	✓	~	
Neutral Screen (Latching Relays only)	V	✓	✓	✓	
Break Before Make Verification			V	V	
Contact Simultaneity			V	V	
Subgroup 3	1	1			
Solderability 2 Samples per Daily Solderability Inspection Lot	V	V	V	V	
Leak Test	V	✓	✓	V	
External Visual and Mechanical Inspection 2/Lot for Dimension and Weight Check	~	V	V	~	

¹ AQL = Acceptable Quality Level

Teledyne Relays: Because in deep space there is no acceptable failure rate

Teledyne Relays has a long history of supplying High Reliability relays for use in space bound vehicles. From the earliest deep space probes, such as

Voyager I, now nearing 21 billion miles out in space, to the next generation of probes scheduled for the

future, Teledyne Relays continues to be the preeminent supplier of Hi-Reliability relays to the space market.

Teledyne Relays Hi-Reliability Specification: TR-HIREL-1

- Eliminates the need for customers to develop and maintain specifications.
- Manufacturing and Quality Assurance requirements are fully defined and documented.
- Meets the general requirements of both ESA/SCC and NASA/GSFC documents.
- Offers options for 100% Group A screening
- Offers options for 3 levels of Lot Acceptance Testing (LAT).

Teledyne Screening Document 0-40-837

NASA approved screening regimen based on NASA/GSFC S-311-P.754



RELAY TYPES

TO-5 Magnetic-Latching Relays

TO-5 Non-Latching Relays

TO-5 Magnetic-Latching, High-Shock Relays

TO-5 Non-Latching, High-Shock Relays

TO-5 Non-Latching, High-Vibration Relays

HI-REL SCREENING CAPABILITIES

100% Open Electrical Inspection

100% Precap Inspection

Fully Automated Small Particle Inspection

(Millipore Clean)

Asynchronous Miss Test

Coil Continuity

Sine Vibration

Random Vibration

High/Low Run In

(Miss Test) -65 °C ± 125 °C

Radiographic Inspection

Mechanical Shock Test

Thermal Shock Test

Acceleration

Radiographic Inspection (X-ray)

Mechanical Shock Test

Thermal Shock Test

Acceleration

Load Banks for a Variety of Life Test Load

Serialized Printed Electrical Data

Continuous Life Testing

Environmental Testing

Vertical Integration

For information or answers to your questions, please visit our website.

APPENDIX: Authorized Distributors

NORTH AMERICA

ALLIED ELECTRONICS

Tel: (800) 433-5700

www.alliedelec.com/search.asp

ASAP ELECTRONICS

Tel: (800) 477-1272 www.asapelectronics.com

Tel: (800) 772-8638 www.em.avnet.com

MASTER DISTRIBUTORS

Tel: (888) 473-5297

www.onlinecomponents.com

MOUSER ELECTRONICS

Tel: (800) 346-6873 www.mouser.com

RICHARDSON ELECTRONICS

Tel: (800) 737-6937 www.rell.com

SHERBURN ELECTRONICS

Tel: (800) 366-3066 www.sherburn.com

BELGIUM & LUXEMBOURG

Nijkerk Electronics B.V.

Tel: +32 (0) 3 544 7066

E-mail: alain.huysmans@nijkerk.be www.nijkerk-ne.com

CHINA & HONG KONG

Fiaco Microelectronics

Beijing Office Tel: 86-10-6503-2171 E-mail: beijing@fiaco.com

Bright Toward Industrial Co., Ltd.

Beijing Office

Tel: 86-10-8200-4979

E-mail: linden_wang@toward.com.cn

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Hot Electronic GmbH

Tel: +49 (0) 89 666 2836 E-mail: info@hot-electronic.de www.hot-electronic.de

MRC Components oHG

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Zettler electronics GmbH

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E-mail: office@zettlerelectronics.com www.zettlerelectronics.com

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LITHUANIA

ARROW Lithuania

Tel: +370-37-759015 E-mail: lithuania@arrownordic.com www.arrowne.com

MALAYSIA

Device Electronics PTE. Ltd.

Tel: (603) 7880 8626/8636 E-mail: ngthomas@devicelect.com

NETHERLANDS

Nijkerk Electronics B.V.

Tel: +32 (0) 3 544 7066

E-mail: alain.huysmans@nijkerk.be

www.nijkerk-ne.com

NORWAY

ARROW Norway A/S

Tel: +47 (0) 21306532

E-mail: stondevoldshagen@arrownordic.com

www.arrowne.com

RUSSIA

Petersburg Electronic Company JSC

Tel: +7 812 4488 777 E-mail: dkizha@pec.spb.ru www.pec.spb.ru

SINGAPORE

Device Electronics PTE, Ltd.

Tel: 65-288 6455

E-mail: ngthomas@devicelect.com

SOUTH AFRICA

RF Design

Tel:

National Smart Call: 0861 753 357 Cape Town: +27 (0) 21 555 8400 Gauteng: +27 (0) 11 695 2200 Durban: +27 (0) 31 266 4534 www.rfdesign.co.za

SWEDEN

ARROW Sweden

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www.arrowne.com

MicroComp Nordic AB

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E-mail: info@microcomp-nordic.se

www.mcnab.se

OEM Electronics

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SWITZERLAND

ENA AG

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Bright Toward Industrial Co., Ltd. Tel: +886-2-822-76000 E-mail: philip@relays.com.tw www.relays.com.tw

UNITED KINGDOM

Advanced Power Components plc

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Arrow Electronics UK Ltd.

Tel: +44 (0) 1279 626 777 www.arrowne.com

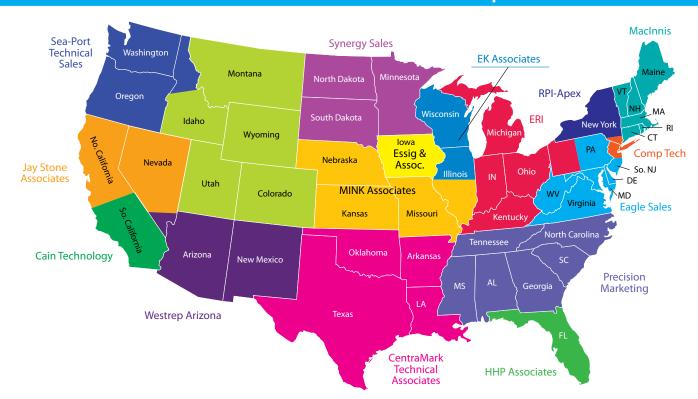
Willow Technologies Ltd.

Tel: +44 (0) 1342 835 234 E-mail: sales@willow.co.uk www.willow.co.uk

2001 Electronic Components Ltd.

Tel: +44 (0) 1438 742 001 E-mail: sales@2001elec.co.uk www.2001elec.co.uk

APPENDIX: Authorized North American Representatives



REPRESENTATIVES

Cain Technology

Southern California 2629 Townsgate Road, Suite 200 Westlake Village, CA 91361 Tel: 805-496-5702 Fax: 805-496-6702 www.caintech.com

Cee-Jay Micro Ltd.

Eastern Canada 155 Terence Matthews Crescent Unit 2 Kanata, Ontario Canada K2M 2A8 Tel: 613-599-5626 www.cjmicro.com

CentraMark Technical Sales Associates

TX, OK and LA 3333 Naaman School Road Garland, TX 75040 Tel: 972-414-8188 Fax: 972-414-6788 www.cmatex.com

Comp-Tech Sales

Northern New Jersey, Metro New York, Long Island 232 Boulevard, Suite 11 Hasbrouck Heights, NJ 07604 Tel: (201) 288-7400 Fax: (201) 288-7583 www.comp-techsales.com

Eagle Sales Corporation

MD, VA, WA DC, Eastern PA,
Southern NJ
3545 Ellicott Mills Drive, Suite 202
Ellicott City, MD 21043
Tel: (410) 203-2317
Fax: (410) 203-2318
www.eaglesales.net

EK & Associates, Inc.

IL, WI 887 E. Wilmette Road, Suite J Paltine, IL 60074 Tel: 847-776-1758 Fax: 847-776-8221 www.ekrep.com

Electronic Representatives, Inc.

IN, OH, MI, KY, West PA 6801 Lake Plaza Drive, Suite D402 Indianapolis, IN 46220 Tel: (317) 915-1414 Fax: (317) 915-1216 www.electronicreps.com

Essig & Associates, Inc.

Iowa 809 N. Compton Drive Hiawatha, IA 52233 Tel: (319) 363-8703 Fax: (319) 363-7224 www.essigassoc.com

HHP Associates, Inc.

Florida 1355 S. International Pkwy, Suite 2471 Lake Mary, FL 32746 Tel: 407-829-8792 Fax: 407-829-8798 www.hhpai.com

Jay Stone & Associates

Northern California 2109 O'Toole Avenue, Suite M San Jose, CA 95131 Tel: 408-428-2500 Fax: 407-428-9000 www.jsarep.com

The MacInnis Company

ME, NH, RI, CT, MA, VT 375 Vanderbilt Avenue Norwood, MA 02062 Tel: (781) 762-8090 Fax: (781) 762-5059 www.macinnis-company.com

MINK Associates

NE, KA, MO 10100 Santa Fe, Suite 311 Overland Park, KS 66212 Tel: (913) 341-8309 Fax: (913) 341-2605 www.minkassoc.com

Precision Marketing Incorporated

MS, AL, TN, GA,NC and SC 5497 Wiles Road, Suite 204 Coconut Creek, FL 33073 Tel: (954) 752-1700 Fax: (954) 973-6335 www.precision-marketing.com

RPI-Apex Associates, Inc.

Upstate New York (excluding Long Island) 54 Andover Street Andover, MA 01810 Tel: 978-475-7055 Fax: 978-475-4749 www.rpi-apex.com

Sea-Port Tech Sales

WA, OR, ID, Western Canada 3630 130th Ave. NE Bellevue, WA 98005 Tel: (425) 702-8300 Fax: (425) 702-8388 www.seaporttech.com

Synergy Sales Representatives, Inc.

MN, ND, SD 5401 Gamble Drive, Suite #105 St. Louis Park, MN 55416 Tel: (952) 544-1686 Fax: (952) 545-2935 www.synergyreps.com

Westrep Arizona AZ, NM, Clark County, NV &

El Paso, TX 6105 S. Ash Avenue, Suite A8 Tempe, AZ 85283 Tel: (480) 820-9932 Fax: (480) 820-9962 www.westrepaz.com

HEADQUARTERS

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Fax: (323) 241-1287

E-mail: relays@teledyne.com

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EUROPE

9-13 Napier Road Wardpark North Cumbernauld G68 OEF Scotland UK

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